S-8252 Series

BATTERY PROTECTION IC FOR 2-SERIAL-CELL PACK

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Rev.4.0_00

The S-8252 Series is a protection IC for 2-serial-cell lithium-ion / lithium polymer rechargeable batteries and includes high-accuracy voltage detection circuits and delay circuits.
The S-8252 Series is suitable for protecting 2-serial-cell rechargeable lithium-ion / lithium polymer battery packs from overcharge, overdischarge, and overcurrent.

■ Features

- High-accuracy voltage detection function for each cell

Overcharge detection voltage n (n = 1, 2)	3.550 V to 4.600 V (5 mV steps)	Accuracy ±20 mV (Ta = +25°C) Accuracy ±25 mV (Ta = –10°C to +60°C)
Overcharge release voltage n (n = 1, 2)	3.150 V to 4.600 V*1	Accuracy ±30 mV
Overdischarge detection voltage n (n = 1, 2)	2.000 V to 3.000 V (10 mV steps)	Accuracy ±50 mV
Overdischarge release voltage n (n = 1, 2)	2.000 V to 3.400 V*2	Accuracy ±100 mV
Discharge overcurrent detection voltage	0.050 V to 0.400 V (10 mV steps)	Accuracy ±10 mV
Load short-circuiting detection voltage	0.500 V to 0.900 V (50 mV steps)	Accuracy ±100 mV
Charge overcurrent detection voltage	–0.400 V to –0.050 V (25 mV steps)	Accuracy ±20 mV

- Charge overcurrent detection function: Available, unavailable
- Detection delay times are generated only by an internal circuit (external capacitors are unnecessary). Accuracy ±20%
- High-withstand voltage (VM pin and CO pin: Absolute maximum rating = 28 V)
- 0 V battery charge: Enabled, inhibited
- Power-down function: Available, unavailable
- Wide operation temperature range: Ta = –40°C to +85°C
- Low current consumption
  - During operation: 8.0 µA max. (Ta = +25°C)
  - During power-down: 0.1 µA max. (Ta = +25°C)
- Lead-free (Sn 100%), halogen-free

***1.** Overcharge release voltage = Overcharge detection voltage – Overcharge hysteresis voltage
(Overcharge hysteresis voltage n (n = 1, 2) can be selected as 0 V or from a range of 0.1 V to 0.4 V in 50 mV steps.)

***2.** Overdischarge release voltage = Overdischarge detection voltage + Overdischarge hysteresis voltage
(Overdischarge hysteresis voltage n (n = 1, 2) can be selected as 0 V or from a range of 0.1 V to 0.7 V in 100 mV steps.)

■ Applications

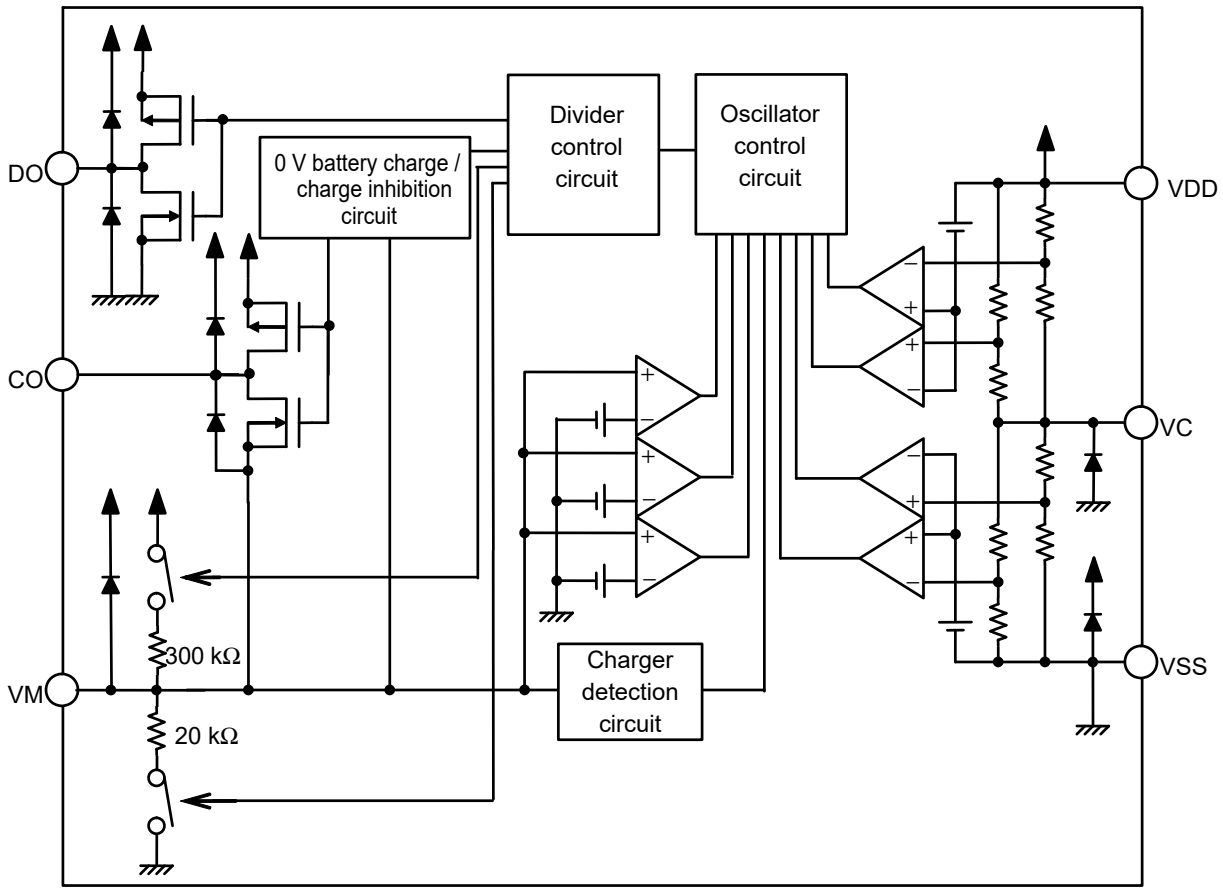
- Lithium-ion rechargeable battery pack
- Lithium polymer rechargeable battery pack

■ Packages

- SOT-23-6
- SNT-6A

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■ Block Diagram



Remark All diodes shown in figure are parasitic diodes.

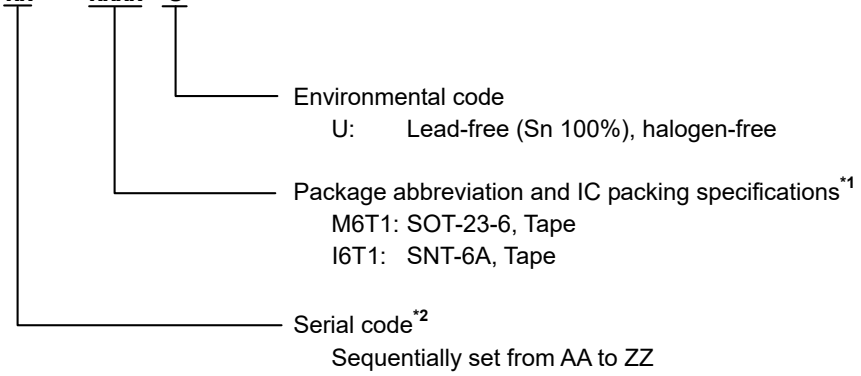
Figure 1

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■ Product Name Structure

1. Product name

S-8252A xx - xxxx U



***1.** Refer to the tape drawing.
***2.** Refer to "**3. Product name list**".

2. Packages

Table 1 Package Drawing Codes

Package Name	Dimension	Tape	Reel	Land
SOT-23-6	MP006-A-P-SD	MP006-A-C-SD	MP006-A-R-SD	–
SNT-6A	PG006-A-P-SD	PG006-A-C-SD	PG006-A-R-SD	PG006-A-L-SD

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3. Product name list

3. 1 SOT-23-6

Table 2 (1 / 2)

Product Name	Over-charge Detection Voltage [V_{CU}]	Over-charge Release Voltage [V_{CL}]	Over-discharge Detection Voltage [V_{DL}]	Over-discharge Release Voltage [V_{DU}]	Discharge Overcurrent Detection Voltage [V_{DIOV}]	Load Short-circuiting Detection Voltage [V_{SHORT}]	Charge Overcurrent Detection Voltage [V_{CIOV}]	0 V Battery Charge	Power-down Function	Delay Time Combination*1
S-8252AAA-M6T1U	4.280 V	4.080 V	2.000 V	2.000 V	0.200 V	0.500 V	−0.100 V	Inhibited	Available	(1)
S-8252AAB-M6T1U	4.325 V	4.075 V	2.200 V	2.900 V	0.210 V	0.500 V	−0.200 V	Inhibited	Available	(1)
S-8252AAC-M6T1U	4.300 V	4.100 V	2.400 V	3.000 V	0.200 V	0.500 V	−0.200 V	Inhibited	Available	(1)
S-8252AAD-M6T1U	4.280 V	4.130 V	2.400 V	2.900 V	0.150 V	0.500 V	−0.150 V	Inhibited	Available	(1)
S-8252AAE-M6T1U	4.350 V	4.150 V	2.300 V	3.000 V	0.300 V	0.500 V	−0.300 V	Enabled	Available	(1)
S-8252AAF-M6T1U	4.350 V	4.100 V	2.400 V	3.000 V	0.150 V	0.500 V	−0.150 V	Enabled	Available	(1)
S-8252AAG-M6T1U	4.300 V	4.150 V	2.800 V	3.000 V	0.150 V	0.500 V	−0.150 V	Enabled	Available	(1)
S-8252AAH-M6T1U	4.250 V	4.100 V	3.000 V	3.000 V	0.200 V	0.500 V	−0.200 V	Enabled	Available	(1)
S-8252AAI-M6T1U	3.650 V	3.450 V	2.000 V	2.700 V	0.200 V	0.500 V	−0.200 V	Enabled	Unavailable	(1)
S-8252AAJ-M6T1U	3.900 V	3.500 V	2.000 V	2.500 V	0.200 V	0.500 V	−0.200 V	Enabled	Unavailable	(1)
S-8252AAK-M6T1U	4.350 V	4.150 V	2.300 V	3.000 V	0.200 V	0.500 V	−0.200 V	Enabled	Available	(1)
S-8252AAL-M6T1U	4.200 V	4.050 V	2.500 V	3.000 V	0.200 V	0.500 V	−0.200 V	Inhibited	Available	(1)
S-8252AAO-M6T1U	4.250 V	4.100 V	2.500 V	3.000 V	0.200 V	0.500 V	−0.100 V	Inhibited	Available	(1)
S-8252AAP-M6T1U	4.350 V	4.150 V	2.200 V	2.900 V	0.200 V	0.500 V	−0.400 V	Inhibited	Available	(1)
S-8252AAQ-M6T1U	4.300 V	4.100 V	2.600 V	3.000 V	0.400 V	0.500 V	−0.400 V	Inhibited	Available	(1)
S-8252AAR-M6T1U	4.300 V	4.100 V	2.600 V	3.000 V	0.400 V	0.500 V	−	Inhibited	Available	(3)
S-8252AAS-M6T1U	4.250 V	4.050 V	2.500 V	3.000 V	0.200 V	0.500 V	−0.200 V	Enabled	Unavailable	(1)
S-8252AAT-M6T1U	4.250 V	4.100 V	2.700 V	3.000 V	0.120 V	0.500 V	−0.050 V	Enabled	Available	(1)
S-8252AAU-M6T1U	4.275 V	4.075 V	2.500 V	2.900 V	0.300 V	0.500 V	−0.100 V	Enabled	Available	(1)
S-8252AAV-M6T1U	4.400 V	4.250 V	2.500 V	2.900 V	0.150 V	0.500 V	−0.100 V	Enabled	Available	(1)
S-8252AAW-M6T1U	4.350 V	4.150 V	2.300 V	3.000 V	0.200 V	0.500 V	−0.400 V	Inhibited	Available	(1)
S-8252AAX-M6T1U	4.230 V	4.030 V	2.750 V	3.050 V	0.150 V	0.500 V	−0.100 V	Inhibited	Available	(1)
S-8252AAY-M6T1U	4.250 V	4.050 V	3.000 V	3.200 V	0.150 V	0.500 V	−0.050 V	Inhibited	Available	(2)
S-8252AAZ-M6T1U	4.225 V	4.075 V	2.400 V	2.900 V	0.150 V	0.500 V	−0.150 V	Inhibited	Available	(1)
S-8252ABA-M6T1U	4.300 V	4.150 V	3.000 V	3.100 V	0.100 V	0.500 V	−0.150 V	Enabled	Available	(1)
S-8252ABB-M6T1U	4.300 V	4.100 V	2.000 V	2.000 V	0.120 V	0.500 V	−	Enabled	Available	(3)
S-8252ABC-M6T1U	4.300 V	4.100 V	2.000 V	2.000 V	0.055 V	0.500 V	−	Enabled	Available	(3)
S-8252ABD-M6T1U	4.300 V	4.100 V	2.400 V	3.000 V	0.200 V	0.500 V	−0.200 V	Inhibited	Available	(4)
S-8252ABE-M6T1U	4.225 V	4.075 V	2.400 V	2.900 V	0.100 V	0.500 V	−0.100 V	Inhibited	Available	(1)
S-8252ABF-M6T1U	4.300 V	4.100 V	2.400 V	2.400 V	0.100 V	0.500 V	−0.100 V	Enabled	Available	(1)
S-8252ABG-M6T1U	4.280 V	4.130 V	2.400 V	2.900 V	0.150 V	0.500 V	−0.150 V	Inhibited	Unavailable	(1)
S-8252ABH-M6T1U	4.300 V	4.100 V	2.400 V	2.400 V	0.150 V	0.500 V	−0.150 V	Enabled	Available	(1)
S-8252ABI-M6T1U	4.425 V	4.225 V	2.500 V	2.800 V	0.150 V	0.500 V	−0.100 V	Inhibited	Unavailable	(1)
S-8252ABQ-M6T1U	4.300 V	4.100 V	2.370 V	2.970 V	0.210 V	0.500 V	−	Inhibited	Unavailable	(3)
S-8252ABR-M6T1U	4.300 V	4.100 V	2.300 V	2.700 V	0.280 V	0.500 V	−0.250 V	Inhibited	Available	(1)
S-8252ABS-M6T1U	4.350 V	4.150 V	2.000 V	2.400 V	0.250 V	0.500 V	−0.400 V	Inhibited	Available	(1)
S-8252ABT-M6T1U	4.450 V	4.250 V	2.300 V	2.700 V	0.280 V	0.500 V	−0.250 V	Inhibited	Available	(1)
S-8252ABU-M6T1U	4.500 V	4.300 V	2.000 V	2.400 V	0.250 V	0.500 V	−0.400 V	Inhibited	Available	(1)
S-8252ABV-M6T1U	4.300 V	4.100 V	2.370 V	2.570 V	0.210 V	0.500 V	−	Inhibited	Unavailable	(3)
S-8252ABW-M6T1U	4.300 V	4.100 V	2.370 V	2.570 V	0.400 V	0.500 V	−	Inhibited	Unavailable	(3)
S-8252ABX-M6T1U	4.350 V	4.150 V	2.100 V	2.400 V	0.250 V	0.500 V	−	Inhibited	Unavailable	(3)
S-8252ABY-M6T1U	4.450 V	4.250 V	2.300 V	2.700 V	0.370 V	0.500 V	−	Inhibited	Unavailable	(3)
S-8252ABZ-M6T1U	4.500 V	4.300 V	2.000 V	2.400 V	0.200 V	0.500 V	−	Inhibited	Unavailable	(3)
S-8252ACA-M6T1U	4.300 V	4.150 V	2.800 V	3.000 V	0.150 V	0.500 V	−0.100 V	Enabled	Available	(5)
S-8252ACB-M6T1U	4.300 V	4.100 V	2.270 V	2.370 V	0.210 V	0.900 V	−	Inhibited	Unavailable	(3)

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Table 2 (2 / 2)

Product Name	Over-charge Detection Voltage [V_{CU}]	Over-charge Release Voltage [V_{CL}]	Over-discharge Detection Voltage [V_{DL}]	Over-discharge Release Voltage [V_{DU}]	Discharge Overcurrent Detection Voltage [V_{DIOV}]	Load Short-circuiting Detection Voltage [V_{SHORT}]	Charge Overcurrent Detection Voltage [V_{CIOV}]	0 V Battery Charge	Power-down Function	Delay Time Combination*1
S-8252ACC-M6T1U	4.300 V	4.100 V	2.280 V	2.380 V	0.250 V	0.900 V	–	Inhibited	Unavailable	(3)
S-8252ACE-M6T1U	4.300 V	4.100 V	2.230 V	2.930 V	0.080 V	0.500 V	–0.075 V	Inhibited	Available	(1)
S-8252ACF-M6T1U	4.225 V	4.075 V	2.400 V	2.900 V	0.190 V	0.500 V	–0.100 V	Inhibited	Available	(5)
S-8252ACI-M6T1U	4.440 V	4.250 V	2.750 V	3.050 V	0.150 V	0.500 V	–0.100 V	Inhibited	Available	(1)
S-8252ACM-M6T1U	4.375 V	4.225 V	2.800 V	3.000 V	0.130 V	0.500 V	–0.075 V	Inhibited	Available	(6)
S-8252ACN-M6T1U	4.280 V	4.180 V	2.500 V	3.000 V	0.250 V	0.500 V	–0.200 V	Enabled	Unavailable	(7)
S-8252ACO-M6T1U	4.300 V	4.100 V	2.300 V	2.700 V	0.280 V	0.500 V	–0.125 V	Inhibited	Available	(5)
S-8252ACP-M6T1U	4.300 V	4.100 V	2.600 V	3.000 V	0.370 V	0.500 V	–	Inhibited	Available	(8)
S-8252ACQ-M6T1U	4.200 V	4.000 V	2.600 V	3.000 V	0.300 V	0.500 V	–	Inhibited	Available	(3)
S-8252ACR-M6T1U	4.250 V	4.050 V	2.200 V	2.600 V	0.300 V	0.500 V	–	Inhibited	Available	(3)
S-8252ACS-M6T1U	4.350 V	4.150 V	2.400 V	3.000 V	0.300 V	0.500 V	–	Inhibited	Available	(3)
S-8252ACT-M6T1U	4.350 V	4.150 V	2.400 V	3.000 V	0.240 V	0.500 V	–	Inhibited	Available	(3)
S-8252ACU-M6T1U	4.300 V	4.100 V	2.400 V	3.000 V	0.280 V	0.500 V	–	Inhibited	Available	(3)
S-8252ACV-M6T1U	4.300 V	4.100 V	2.400 V	3.000 V	0.210 V	0.500 V	–	Inhibited	Available	(8)
S-8252ACW-M6T1U	4.350 V	4.150 V	2.000 V	2.400 V	0.200 V	0.500 V	–	Inhibited	Available	(8)
S-8252ACX-M6T1U	4.350 V	4.150 V	2.000 V	2.400 V	0.250 V	0.500 V	–	Inhibited	Available	(3)
S-8252ACY-M6T1U	4.250 V	4.050 V	2.000 V	2.500 V	0.200 V	0.500 V	–0.100 V	Inhibited	Available	(7)
S-8252ADC-M6T1U	3.900 V	3.500 V	2.000 V	2.500 V	0.200 V	0.500 V	–0.200 V	Inhibited	Unavailable	(1)

***1.** Refer to **Table 4** about the details of the delay time combinations.

Remark Please contact our sales representatives for products other than the above.

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3. 2 SNT-6A

Table 3

Product Name	Over-charge Detection Voltage [V_{CU}]	Over-charge Release Voltage [V_{CL}]	Over-discharge Detection Voltage [V_{DL}]	Over-discharge Release Voltage [V_{DU}]	Discharge Overcurrent Detection Voltage [V_{DIOV}]	Load Short-circuiting Detection Voltage [V_{SHORT}]	Charge Overcurrent Detection Voltage [V_{CIOV}]	0 V Battery Charge	Power-down Function	Delay Time Combination*1
S-8252AAA-I6T1U	4.280 V	4.080 V	2.000 V	2.000 V	0.200 V	0.500 V	−0.100 V	Inhibited	Available	(1)
S-8252AAH-I6T1U	4.250 V	4.100 V	3.000 V	3.000 V	0.200 V	0.500 V	−0.200 V	Enabled	Available	(1)
S-8252AAM-I6T1U	4.250 V	4.050 V	2.400 V	3.000 V	0.100 V	0.500 V	−0.100 V	Enabled	Available	(1)
S-8252AAN-I6T1U	4.325 V	4.075 V	2.200 V	2.900 V	0.210 V	0.500 V	−0.100 V	Enabled	Available	(1)
S-8252AAY-I6T1U	4.250 V	4.050 V	3.000 V	3.200 V	0.150 V	0.500 V	−0.050 V	Inhibited	Available	(2)
S-8252ABJ-I6T1U	4.300 V	4.100 V	2.400 V	3.000 V	0.210 V	0.500 V	−0.250 V	Inhibited	Available	(1)
S-8252ABK-I6T1U	4.350 V	4.150 V	2.300 V	2.900 V	0.160 V	0.500 V	−0.400 V	Inhibited	Available	(1)
S-8252ABL-I6T1U	4.300 V	4.100 V	2.400 V	2.600 V	0.240 V	0.500 V	−0.200 V	Inhibited	Available	(5)
S-8252ABM-I6T1U	4.350 V	4.150 V	2.300 V	2.500 V	0.170 V	0.500 V	−0.400 V	Inhibited	Available	(5)
S-8252ABO-I6T1U	4.300 V	4.100 V	2.300 V	2.700 V	0.230 V	0.500 V	−0.250 V	Inhibited	Available	(5)
S-8252ABP-I6T1U	4.350 V	4.150 V	2.000 V	2.400 V	0.190 V	0.500 V	−0.400 V	Inhibited	Available	(5)
S-8252ACD-I6T1U	4.280 V	4.080 V	2.000 V	2.000 V	0.170 V	0.500 V	−0.100 V	Inhibited	Available	(1)
S-8252ACG-I6T1U	4.280 V	4.080 V	2.000 V	2.000 V	0.170 V	0.500 V	−0.100 V	Inhibited	Available	(5)
S-8252ACH-I6T1U	4.470 V	4.370 V	2.750 V	3.050 V	0.120 V	0.500 V	−0.100 V	Inhibited	Available	(5)
S-8252ACJ-I6T1U	4.325 V	4.075 V	2.000 V	2.200 V	0.190 V	0.900 V	−	Inhibited	Available	(3)
S-8252ACK-I6T1U	4.300 V	4.100 V	2.300 V	2.700 V	0.340 V	0.500 V	−0.300 V	Inhibited	Available	(5)
S-8252ACL-I6T1U	4.350 V	4.150 V	2.000 V	2.400 V	0.330 V	0.500 V	−0.400 V	Inhibited	Available	(5)
S-8252ACZ-I6T1U	4.300 V	4.100 V	2.400 V	2.600 V	0.150 V	0.500 V	−0.400 V	Inhibited	Available	(9)
S-8252ADA-I6T1U	4.300 V	4.100 V	2.400 V	2.600 V	0.230 V	0.500 V	−0.150 V	Inhibited	Available	(10)
S-8252ADB-I6T1U	4.350 V	4.150 V	2.000 V	2.400 V	0.140 V	0.500 V	−0.400 V	Inhibited	Available	(9)
S-8252ADD-I6T1U	4.300 V	4.100 V	2.300 V	2.700 V	0.240 V	0.500 V	−0.175 V	Inhibited	Available	(5)
S-8252ADE-I6T1U	4.350 V	4.150 V	2.000 V	2.400 V	0.180 V	0.500 V	−0.150 V	Inhibited	Available	(5)
S-8252ADF-I6T1U	4.490 V	4.290 V	2.300 V	2.700 V	0.070 V	0.500 V	−0.075 V	Enabled	Unavailable	(11)
S-8252ADH-I6T1U	4.250 V	4.050 V	2.400 V	3.000 V	0.150 V	0.900 V	−	Enabled	Available	(3)
S-8252ADI-I6T1U	4.350 V	4.150 V	2.300 V	2.900 V	0.250 V	0.900 V	−	Inhibited	Available	(3)
S-8252ADJ-I6T1U	4.350 V	4.150 V	2.300 V	2.900 V	0.100 V	0.900 V	−	Enabled	Available	(3)
S-8252ADK-I6T1U	4.350 V	4.150 V	2.300 V	2.700 V	0.220 V	0.900 V	−	Inhibited	Unavailable	(12)
S-8252ADL-I6T1U	4.350 V	4.150 V	2.000 V	2.200 V	0.190 V	0.900 V	−	Inhibited	Available	(13)
S-8252ADM-I6T1U	4.350 V	4.150 V	2.300 V	2.900 V	0.200 V	0.900 V	−	Inhibited	Available	(3)

***1.** Refer to **Table 4** about the details of the delay time combinations.

Remark Please contact our sales representatives for products other than the above.

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Table 4

Delay Time Combination	Overcharge Detection Delay Time [t_{CU}]	Overdischarge Detection Delay Time [t_{DL}]	Discharge Overcurrent Detection Delay Time [t_{DIOV}]	Load Short-circuiting Detection Delay Time [t_{SHORT}]	Charge Overcurrent Detection Delay Time [t_{CIOV}]
(1)	1.0 s	128 ms	8 ms	280 µs	8 ms
(2)	1.0 s	512 ms	8 ms	280 µs	8 ms
(3)	1.0 s	128 ms	8 ms	280 µs	–
(4)	1.0 s	128 ms	8 ms	1 ms	8 ms
(5)	1.0 s	128 ms	16 ms	280 µs	8 ms
(6)	1.0 s	128 ms	32 ms	280 µs	8 ms
(7)	1.0 s	512 ms	8 ms	1 ms	8 ms
(8)	1.0 s	128 ms	8 ms	1 ms	–
(9)	1.0 s	128 ms	128 ms	280 µs	16 ms
(10)	1.0 s	128 ms	16 ms	280 µs	16 ms
(11)	1.0 s	128 ms	32 ms	500 µs	16 ms
(12)	1.0 s	128 ms	16 ms	1 ms	–
(13)	1.0 s	128 ms	8 ms	500 µs	–

Remark The delay times can be changed within the range listed in **Table 5**. For details, please contact our sales representatives.

Table 5

Delay Time	Symbol	Selection Range			Remark
Overcharge detection delay time	t_{CU}	256 ms	512 ms	1.0 s*1	Select a value from the left.
Overdischarge detection delay time	t_{DL}	32 ms	64 ms	128 ms*1	Select a value from the left.
Discharge overcurrent detection delay time	t_{DIOV}	4 ms	8 ms*1	16 ms	Select a value from the left.
Load short-circuiting detection delay time	t_{SHORT}	280 µs*1	500 µs	1 ms	Select a value from the left.
Charge overcurrent detection delay time	t_{CIOV}	4 ms	8 ms*1	16 ms	Select a value from the left.

***1.** This value is the delay time of the standard products.

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■ Pin Configurations

1. SOT-23-6

Top view

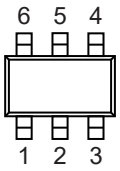


Figure 2

Table 6

Pin No.	Symbol	Description
1	DO	Connection pin of discharge control FET gate (CMOS output)
2	CO	Connection pin of charge control FET gate (CMOS output)
3	VM	Voltage detection pin between VM pin and VSS pin (Overcurrent / charger detection pin)
4	VC	Connection pin for negative voltage of battery 1 and connection pin for positive voltage of battery 2
5	VDD	Connection pin for positive power supply input and connection pin for positive voltage of battery 1
6	VSS	Connection pin for negative power supply input and connection pin for negative voltage of battery 2

2. SNT-6A

Top view



Figure 3

Table 7

Pin No.	Symbol	Description
1	VM	Voltage detection pin between VM pin and VSS pin (Overcurrent / charger detection pin)
2	CO	Connection pin of charge control FET gate (CMOS output)
3	DO	Connection pin of discharge control FET gate (CMOS output)
4	VSS	Connection pin for negative power supply input and connection pin for negative voltage of battery 2
5	VDD	Connection pin for positive power supply input and connection pin for positive voltage of battery 1
6	VC	Connection pin for negative voltage of battery 1 and connection pin for positive voltage of battery 2

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■ Absolute Maximum Ratings

Table 8

(Ta = +25°C unless otherwise specified)

Item		Symbol	Applied pin	Absolute Maximum Rating	Unit
Input voltage between VDD pin and VSS pin		V_{DS}	VDD	V_{SS} – 0.3 to V_{SS} + 12	V
VC pin input voltage		V_{VC}	VC	V_{SS} – 0.3 to V_{DD} + 0.3	V
VM pin input voltage		V_{VM}	VM	V_{DD} – 28 to V_{DD} + 0.3	V
DO pin output voltage		V_{DO}	DO	V_{SS} – 0.3 to V_{DD} + 0.3	V
CO pin output voltage		V_{CO}	CO	V_{VM} – 0.3 to V_{DD} + 0.3	V
Power dissipation	SOT-23-6	P_D	–	650*1	mW
	SNT-6A		–	400*1	mW
Operation ambient temperature		T_{opr}	–	–40 to +85	°C
Storage temperature		T_{stg}	–	–55 to +125	°C

***1.** When mounted on board
[Mounted board]
(1) Board size: 114.3 mm × 76.2 mm × t1.6 mm
(2) Board name: JEDEC STANDARD51-7

Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.

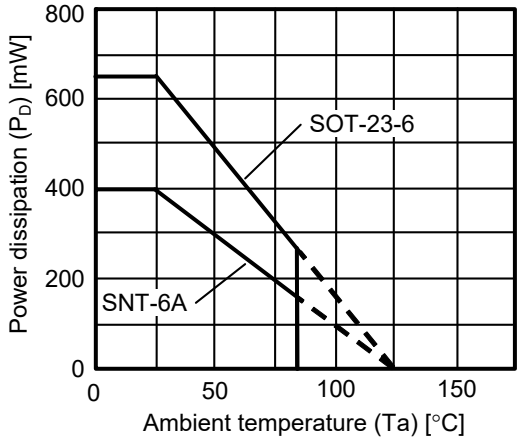


Figure 4 Package Power Dissipation (When Mounted on Board)

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■ Electrical Characteristics

1. Ta = +25°C

Table 9

(Ta = +25°C unless otherwise specified)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit	Test Circuit
DETECTION VOLTAGE							
Overcharge detection voltage n (n = 1, 2)	V_{CUn}	–	V_{CU} – 0.020	V_{CU}	V_{CU} + 0.020	V	1
		Ta = –10°C to +60°C*1	V_{CU} – 0.025	V_{CU}	V_{CU} + 0.025	V	1
Overcharge release voltage n (n = 1, 2)	V_{CLn}	$V_{CL} \neq V_{CU}$	V_{CL} – 0.030	V_{CL}	V_{CL} + 0.030	V	1
		$V_{CL} = V_{CU}$	V_{CL} – 0.030	V_{CL}	V_{CL} + 0.020	V	1
Overdischarge detection voltage n (n = 1, 2)	V_{DLn}	–	V_{DL} – 0.050	V_{DL}	V_{DL} + 0.050	V	2
Overdischarge release voltage n (n = 1, 2)	V_{DUn}	$V_{DL} \neq V_{DU}$	V_{DU} – 0.100	V_{DU}	V_{DU} + 0.100	V	2
		$V_{DL} = V_{DU}$	V_{DU} – 0.050	V_{DU}	V_{DU} + 0.050	V	2
Discharge overcurrent detection voltage	V_{DIOV}	–	V_{DIOV} – 0.010	V_{DIOV}	V_{DIOV} + 0.010	V	2
Load short-circuiting detection voltage	V_{SHORT}	–	V_{SHORT} – 0.100	V_{SHORT}	V_{SHORT} + 0.100	V	2
DETECTION VOLTAGE (WITH CHARGE OVERCURRENT DETECTION FUNCTION)							
Charge overcurrent detection voltage	V_{CIOV}	–	V_{CIOV} – 0.020	V_{CIOV}	V_{CIOV} + 0.020	V	2
DETECTION VOLTAGE (WITHOUT CHARGE OVERCURRENT DETECTION FUNCTION)							
Charger detection voltage	V_{CHA}	–	–1.0	–0.7	–0.4	V	2
0 V BATTERY CHARGE							
0 V battery charge starting charger voltage	V_{0CHA}	0 V battery charge enabled	0.0	0.7	1.0	V	2
0 V battery charge inhibition battery voltage	V_{0INH}	0 V battery charge inhibited	0.4	0.8	1.1	V	2
INTERNAL RESISTANCE							
Resistance between VM pin and VDD pin	R_{VMD}	V1 = V2 = 1.8 V, V3 = 0 V	100	300	900	kΩ	3
Resistance between VM pin and VSS pin	R_{VMS}	V1 = V2 = 3.5 V, V3 = 1.0 V	10	20	40	kΩ	3
INPUT VOLTAGE							
Operation voltage between VDD pin and VSS pin	V_{DSOP1}	–	1.5	–	10	V	–
INPUT CURRENT (WITH POWR-DOWN FUNCTION)							
Current consumption during operation	I_{OPE}	V1 = V2 = 3.5 V, V3 = 0 V	–	4.0	8.0	µA	2
Current consumption during power-down	I_{PDN}	V1 = V2 = 1.5 V, V3 = 3.0 V	–	–	0.1	µA	2
VC pin current	I_{VC}	V1 = V2 = 3.5 V, V3 = 0 V	0.0	0.7	1.5	µA	2
INPUT CURRENT (WITHOUT POWR-DOWN FUNCTION)							
Current consumption during operation	I_{OPE}	V1 = V2 = 3.5 V, V3 = 0 V	–	4.0	8.0	µA	2
Current consumption during overdischarge	I_{OPED}	V1 = V2 = 1.5 V, V3 = 3.0 V	–	2.5	5.0	µA	2
VC pin current	I_{VC}	V1 = V2 = 3.5 V, V3 = 0 V	0.0	0.7	1.5	µA	2
OUTPUT RESISTANCE							
CO pin resistance "H"	R_{COH}	V1 = V2 = 3.5 V, V3 = 0 V, V4 = 6.5 V	2.5	5	10	kΩ	4
CO pin resistance "L"	R_{COL}	V1 = V2 = 4.7 V, V3 = 0 V, V4 = 0.5 V	2.5	5	10	kΩ	4
DO pin resistance "H"	R_{DOH}	V1 = V2 = 3.5 V, V3 = 0 V, V5 = 6.5 V	5	10	20	kΩ	4
DO pin resistance "L"	R_{DOL}	V1 = V2 = 1.8 V, V3 = 3.6 V, V5 = 0.5 V	5	10	20	kΩ	4
DELAY TIME							
Overcharge detection delay time	t_{CU}	–	$t_{CU} \times 0.8$	t_{CU}	$t_{CU} \times 1.2$	–	5
Overdischarge detection delay time	t_{DL}	–	$t_{DL} \times 0.8$	t_{DL}	$t_{DL} \times 1.2$	–	5
Discharge overcurrent detection delay time	t_{DIOV}	–	$t_{DIOV} \times 0.8$	t_{DIOV}	$t_{DIOV} \times 1.2$	–	5
Load short-circuiting detection delay time	t_{SHORT}	–	$t_{SHORT} \times 0.8$	t_{SHORT}	$t_{SHORT} \times 1.2$	–	5
Charge overcurrent detection delay time	t_{CIOV}	–	$t_{CIOV} \times 0.8$	t_{CIOV}	$t_{CIOV} \times 1.2$	–	5

***1.** Since products are not screened at high and low temperature, the specification for this temperature range is guaranteed by design, not tested in production.

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2. Ta = –40°C to +85°C*1

Table 10

(Ta = –40°C to +85°C*1 unless otherwise specified)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit	Test Circuit
DETECTION VOLTAGE							
Overcharge detection voltage n (n = 1, 2)	V_{CUn}	–	V_{CU} – 0.045	V_{CU}	V_{CU} + 0.030	V	1
Overcharge release voltage n (n = 1, 2)	V_{CLn}	$V_{CL} \neq V_{CU}$	V_{CL} – 0.070	V_{CL}	V_{CL} + 0.040	V	1
		$V_{CL} = V_{CU}$	V_{CL} – 0.050	V_{CL}	V_{CL} + 0.030	V	1
Overdischarge detection voltage n (n =1, 2)	V_{DLn}	–	V_{DL} – 0.085	V_{DL}	V_{DL} + 0.060	V	2
Overdischarge release voltage n (n =1, 2)	V_{DUn}	$V_{DL} \neq V_{DU}$	V_{DU} – 0.140	V_{DU}	V_{DU} + 0.110	V	2
		$V_{DL} = V_{DU}$	V_{DU} – 0.085	V_{DU}	V_{DU} + 0.060	V	2
Discharge overcurrent detection voltage	V_{DIOV}	–	V_{DIOV} – 0.010	V_{DIOV}	V_{DIOV} + 0.010	V	2
Load short-circuiting detection voltage	V_{SHORT}	–	V_{SHORT} – 0.100	V_{SHORT}	V_{SHORT} + 0.100	V	2
DETECTION VOLTAGE (WITH CHARGE OVERCURRENT DETECTION FUNCTION)							
Charge overcurrent detection voltage	V_{CIOV}	–	V_{CIOV} – 0.020	V_{CIOV}	V_{CIOV} + 0.020	V	2
DETECTION VOLTAGE (WITHOUT CHARGE OVERCURRENT DETECTION FUNCTION)							
Charger detection voltage	V_{CHA}	–	–1.2	–0.7	–0.2	V	2
0 V BATTERY CHARGE							
0 V battery charge starting charger voltage	V_{0CHA}	0 V battery charge enabled	0.0	0.7	1.5	V	2
0 V battery charge inhibition battery voltage	V_{0INH}	0 V battery charge inhibited	0.3	0.8	1.3	V	2
INTERNAL RESISTANCE							
Resistance between VM pin and VDD pin	R_{VMD}	V1 = V2 = 1.8 V, V3 = 0 V	78	300	1310	kΩ	3
Resistance between VM pin and VSS pin	R_{VMS}	V1 = V2 = 3.5 V, V3 = 1.0 V	7.2	20	44	kΩ	3
INPUT VOLTAGE							
Operation voltage between VDD pin and VSS pin	V_{DSOP1}	–	1.5	–	10	V	–
INPUT CURRENT (WITH POWER-DOWN FUNCTION)							
Current consumption during operation	I_{OPE}	V1 = V2 = 3.5 V, V3 = 0 V	–	4.5	8.5	µA	2
Current consumption during power-down	I_{PDN}	V1 = V2 = 1.5 V, V3 = 3.0 V	–	–	0.15	µA	2
VC pin current	I_{VC}	V1 = V2 = 3.5 V, V3 = 0 V	0.0	1.2	2.0	µA	2
INPUT CURRENT (WITHOUT POWER-DOWN FUNCTION)							
Current consumption during operation	I_{OPE}	V1 = V2 = 3.5 V, V3 = 0 V	–	4.5	8.5	µA	2
Current consumption during overdischarge	I_{OPED}	V1 = V2 = 1.5 V, V3 = 3.0 V	–	2.5	5.5	µA	2
VC pin current	I_{VC}	V1 = V2 = 3.5 V, V3 = 0 V	0.0	1.2	2.0	µA	2
OUTPUT RESISTANCE							
CO pin resistance "H"	R_{COH}	V1 = V2 = 3.5 V, V3 = 0 V, V4 = 6.5 V	1.2	5	15	kΩ	4
CO pin resistance "L"	R_{COL}	V1 = V2 = 4.7 V, V3 = 0 V, V4 = 0.5 V	1.2	5	15	kΩ	4
DO pin resistance "H"	R_{DOH}	V1 = V2 = 3.5 V, V3 = 0 V, V5 = 6.5 V	2.4	10	30	kΩ	4
DO pin resistance "L"	R_{DOL}	V1 = V2 = 1.8 V, V3 = 3.6 V, V5 = 0.5 V	2.4	10	30	kΩ	4
DELAY TIME							
Overcharge detection delay time	t_{CU}	–	$t_{CU} \times 0.3$	t_{CU}	$t_{CU} \times 2.0$	–	5
Overdischarge detection delay time	t_{DL}	–	$t_{DL} \times 0.3$	t_{DL}	$t_{DL} \times 2.0$	–	5
Discharge overcurrent detection delay time	t_{DIOV}	–	$t_{DIOV} \times 0.3$	t_{DIOV}	$t_{DIOV} \times 2.0$	–	5
Load short-circuiting detection delay time	t_{SHORT}	–	$t_{SHORT} \times 0.3$	t_{SHORT}	$t_{SHORT} \times 2.0$	–	5
Charge overcurrent detection delay time	t_{CIOV}	–	$t_{CIOV} \times 0.3$	t_{CIOV}	$t_{CIOV} \times 2.0$	–	5

***1.** Since products are not screened at high and low temperature, the specification for this temperature range is guaranteed by design, not tested in production.

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■ Test Circuits

Caution Unless otherwise specified, the output voltage levels "H" and "L" at CO pin (V_{CO}) and DO pin (V_{DO}) are judged by the threshold voltage (1.0 V) of the N-channel FET. Judge the CO pin level with respect to V_{VM} and the DO pin level with respect to V_{SS}.

1. Overcharge detection voltage, overcharge release voltage (Test circuit 1)

Overcharge detection voltage (V_{CU1}) is defined as the voltage V1 at which V_{CO} goes from "H" to "L" when the voltage V1 is gradually increased from the starting condition of V1 = V2 = V_{CU} – 0.05 V, V3 = 0 V. Overcharge release voltage (V_{CL1}) is defined as the voltage V1 at which V_{CO} goes from "L" to "H" when the voltage V1 is then gradually decreased after setting V2 = 3.5 V. Overcharge hysteresis voltage (V_{HC1}) is defined as the difference between V_{CU1} and V_{CL1}.
Overcharge detection voltage (V_{CU2}) is defined as the voltage V2 at which V_{CO} goes from "H" to "L" when the voltage V2 is gradually increased from the starting condition of V1 = V2 = V_{CU} – 0.05 V, V3 = 0 V. Overcharge release voltage (V_{CL2}) is defined as the voltage V2 at which V_{CO} goes from "L" to "H" when the voltage V2 is then gradually decreased after setting V1 = 3.5 V. Overcharge hysteresis voltage (V_{HC2}) is defined as the difference between V_{CU2} and V_{CL2}.

2. Overdischarge detection voltage, overdischarge release voltage (Test circuit 2)

Overdischarge detection voltage (V_{DL1}) is defined as the voltage V1 at which V_{DO} goes from "H" to "L" when the voltage V1 is gradually decreased from the starting condition of V1 = V2 = 3.5 V, V3 = 0 V. Overdischarge release voltage (V_{DU1}) is defined as the voltage V1 at which V_{DO} goes from "L" to "H" when the voltage V1 is then gradually increased. Overdischarge hysteresis voltage (V_{HD1}) is defined as the difference between V_{DU1} and V_{DL1}.
Overdischarge detection voltage (V_{DL2}) is defined as the voltage V2 at which V_{DO} goes from "H" to "L" when the voltage V2 is gradually decreased from the starting condition of V1 = V2 = 3.5 V, V3 = 0 V. Overdischarge release voltage (V_{DU2}) is defined as the voltage V2 at which V_{DO} goes from "L" to "H" when the voltage V2 is then gradually increased. Overdischarge hysteresis voltage (V_{HD2}) is defined as the difference between V_{DU2} and V_{DL2}.

3. Discharge overcurrent detection voltage (Test circuit 2)

Discharge overcurrent detection voltage (V_{DIOV}) is defined as the voltage V3 whose delay time for changing V_{DO} from "H" to "L" is discharge overcurrent detection delay time (t_{DIOV}) when the voltage V3 is increased from the starting condition of V1 = V2 = 3.5 V, V3 = 0 V.

4. Load short-circuiting detection voltage (Test circuit 2)

Load short-circuiting detection voltage (V_{SHORT}) is defined as the voltage V3 whose delay time for changing V_{DO} from "H" to "L" is load short-circuiting detection delay time (t_{SHORT}) when the voltage V3 is increased from the starting condition of V1 = V2 = 3.5 V, V3 = 0 V.

5. Charge overcurrent detection voltage, charger detection voltage (Test circuit 2)

5. 1 With charge overcurrent detection function

Charge overcurrent detection voltage (V_{CIOV}) is defined as the voltage V3 whose delay time for changing V_{CO} from "H" to "L" is charge overcurrent detection delay time (t_{CIOV}) when the voltage V3 is decreased from the starting condition of V1 = V2 = 3.5 V, V3 = 0 V.

5. 2 Without charge overcurrent detection function

Charger detection voltage (V_{CHA}) is defined as the voltage V3 at which V_{CO} goes from "H" to "L" when the voltage V3 is decreased from the starting condition of V1 = V2 = 3.5 V, V3 = 0 V.

6. Current consumption during operation (Test circuit 2)

The current consumption during operation (I_{OPE}) is the current that flows through the VDD pin (I_{DD}) under the set conditions of V1 = V2 = 3.5 V, V3 = 0 V.

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7. VC pin current (Test circuit 2)

The VC pin current (I_{VC}) is the current that flows through the VC pin (I_{VC}) under the set conditions of V1 = V2 = 3.5 V, V3 = 0 V.

8. Current consumption during power-down, current consumption during overdischarge (Test circuit 2)

8. 1 With power-down function

The current consumption during power-down (I_{PDN}) is the current that flows through the VSS pin (I_{SS}) under the set conditions of V1 = V2 = 1.5 V, V3 = 3.0 V.

8. 2 Without power-down function

The current consumption during overdischarge (I_{OPED}) is the current that flows through the VSS pin (I_{SS}) under the set conditions of V1 = V2 = 1.5 V, V3 = 3.0 V.

9. Resistance between VM pin and VDD pin (Test circuit 3)

R_{VMD} is the resistance between VM pin and VDD pin under the set conditions of V1 = V2 = 1.8 V, V3 = 0 V.

10. Resistance between VM pin and VSS pin (Test circuit 3)

R_{VMS} is the resistance between VM pin and VSS pin under the set conditions of V1 = V2 = 3.5 V, V3 = 1.0 V.

11. CO pin resistance "H" (Test circuit 4)

The CO pin resistance "H" (R_{COH}) is the resistance between VDD pin and CO pin under the set conditions of V1 = V2 = 3.5 V, V3 = 0 V, V4 = 6.5 V.

12. CO pin resistance "L" (Test circuit 4)

The CO pin resistance "L" (R_{COL}) is the resistance between VM pin and CO pin under the set conditions of V1 = V2 = 4.7 V, V3 = 0 V, V4 = 0.5 V.

13. DO pin resistance "H" (Test circuit 4)

The DO pin resistance "H" (R_{DOH}) is the resistance between VDD pin and DO pin under the set conditions of V1 = V2 = 3.5 V, V3 = 0 V, V5 = 6.5 V

14. DO pin resistance "L" (Test circuit 4)

The DO pin resistance "L" (R_{DOL}) is the resistance between VSS pin and DO pin under the set conditions of V1 = V2 = 1.8 V, V3 = 0 V, V5 = 0.5 V.

15. Overcharge detection delay time (Test circuit 5)

The overcharge detection delay time (t_{CU}) is the time needed for V_{CO} to go to "L" just after the voltage V1 increases and exceeds V_{CU} under the set condition of V1 = V2 = 3.5 V, V3 = 0 V.

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16. Overdischarge detection delay time (Test circuit 5)

The overdischarge detection delay time (t_{DL}) is the time needed for V_{DO} to go to "L" after the voltage V1 decreases and falls below V_{DL} under the set condition of V1 = V2 = 3.5 V, V3 = 0 V.

17. Discharge overcurrent detection delay time (Test circuit 5)

The discharge overcurrent detection delay time (t_{DIOV}) is the time needed for V_{DO} to go to "L" after the voltage V3 increases and exceeds V_{DIOV} under the set conditions of V1 = V2 = 3.5 V, V3 = 0 V.

18. Load short-circuiting detection delay time (Test circuit 5)

The load short-circuiting detection delay time (t_{SHORT}) is the time needed for V_{DO} to go to "L" after the voltage V3 increases and exceeds V_{SHORT} under the set conditions of V1 = V2 = 3.5 V, V3 = 0 V.

19. Charge overcurrent detection delay time (Test circuit 5)

The charge overcurrent detection delay time (t_{CIOV}) is the time needed for V_{CO} to go to "L" after the voltage V3 decreases and falls below V_{CIOV} under the set condition of V1 = V2 = 3.5 V, V3 = 0 V.

20. 0 V battery charge starting charger voltage (0 V battery charge enabled) (Test circuit 2)

The 0 V battery charge starting charger voltage (V_{0CHA}) is defined as the absolute value of voltage V3 at which V_{CO} goes to "H" ($V_{CO} = V_{DD}$) when the voltage V3 is gradually decreased from the starting condition of V1 = V2 = V3 = 0 V.

21. 0 V battery charge inhibition battery voltage (0 V battery charge inhibited) (Test circuit 2)

The 0 V battery charge inhibition battery voltage (V_{0INH}) is defined as the voltage V1 at which V_{CO} goes to "L" (V_{VM} + 0.1 V or lower) when the voltage V1 is gradually decreased, after setting V1 = V2 = 1.5 V, V3 = –6.0 V.

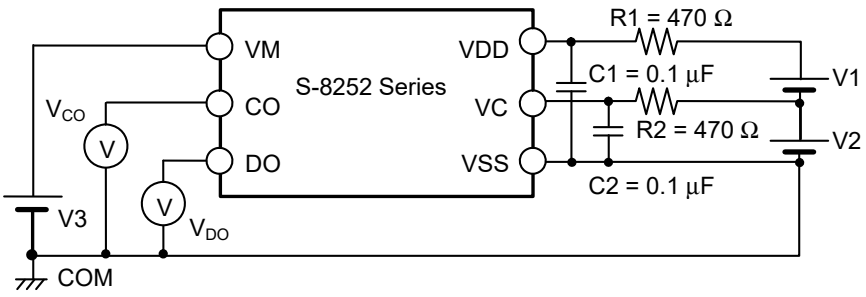


Figure 5 Test Circuit 1

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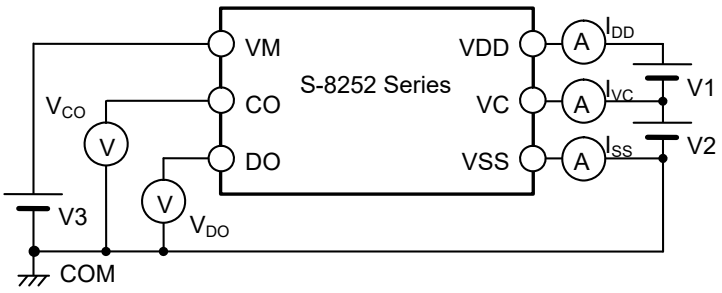


Figure 6 Test Circuit 2

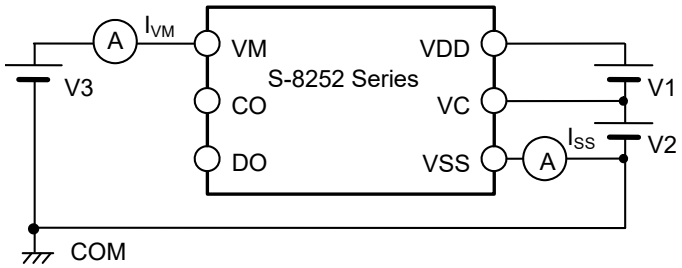


Figure 7 Test Circuit 3

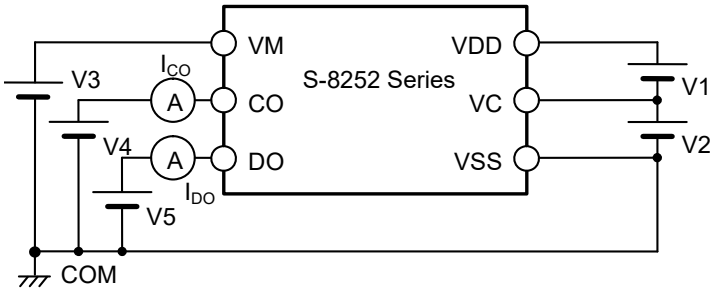


Figure 8 Test Circuit 4

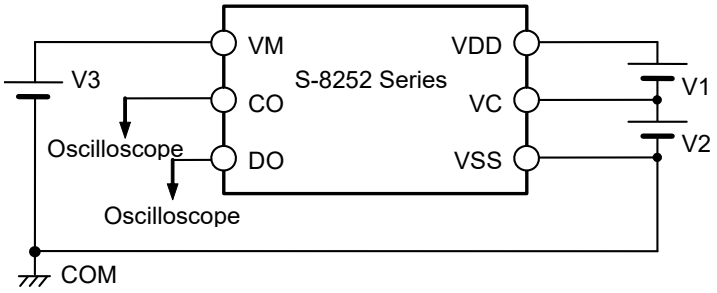


Figure 9 Test Circuit 5

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■ Operation

Remark Refer to the "■ **Battery Protection IC Connection Example**".

Caution Unless otherwise specified, the VM pin voltage is based on V_{SS}.

1. Normal status

1. 1 With charge overcurrent detection function

The S-8252 Series monitors the voltage of the battery connected between the VDD pin and VSS pin and the voltage difference between the VM pin and VSS pin to control charging and discharging. When the battery voltage is in the range from overdischarge detection voltage (V_{DL}) to overcharge detection voltage (V_{CU}), and the VM pin voltage is in the range from the charge overcurrent detection voltage (V_{CIOV}) to discharge overcurrent detection voltage (V_{DIOV}), The S-8252 Series turns both the charging and discharging control FETs on. This condition is called the normal status, and in this condition charging and discharging can be carried out freely.
The resistance (R_{VMD}) between the VM pin and VDD pin, and the resistance (R_{VMS}) between the VM pin and VSS pin are not connected in the normal status.

Caution When the battery is connected for the first time, discharging may not be enabled. In this case, short the VM pin and VSS pin, or set the VM pin voltage at the level of V_{CIOV} or more and V_{DIOV} or less by connecting the charger. The S-8252 Series then returns to the normal status.

1. 2 Without charge overcurrent detection function

The S-8252 Series monitors the voltage of the battery connected between the VDD pin and VSS pin and the voltage difference between the VM pin and VSS pin to control charging and discharging. When the battery voltage is in the range from overdischarge detection voltage (V_{DL}) to overcharge detection voltage (V_{CU}), and the VM pin voltage is in the range from the charger detection voltage (V_{CHA}) to discharge overcurrent detection voltage (V_{DIOV}), The S-8252 Series turns both the charging and discharging control FETs on. This condition is called the normal status, and in this condition charging and discharging can be carried out freely.
The resistance (R_{VMD}) between the VM pin and VDD pin, and the resistance (R_{VMS}) between the VM pin and VSS pin are not connected in the normal status.

Caution When the battery is connected for the first time, discharging may not be enabled. In this case, short the VM pin and VSS pin, or set the VM pin voltage at the level of V_{CHA} or more and V_{DIOV} or less by connecting the charger. The S-8252 Series then returns to the normal status.

2. Overcharge status

When the battery voltage becomes higher than V_{CU} during charging in the normal status and detection continues for the overcharge detection delay time (t_{CU}) or longer, the S-8252 Series turns the charging control FET off to stop charging. This condition is called the overcharge status.
R_{VMD} and R_{VMS} are not connected in the overcharge status.
The overcharge status is released in the following two cases ((1) and (2)).

(1) In the case that the VM pin voltage is lower than V_{DIOV}, the S-8252 Series releases the overcharge status when the battery voltage falls below V_{CL}.
(2) In the case that the VM pin voltage is higher than or equal to V_{DIOV}, the S-8252 Series releases the overcharge status when the battery voltage falls below V_{CU}.

When the discharge is started by connecting a load after the overcharge detection, the VM pin voltage rises more than the voltage at VSS pin due to the V_f voltage of the parasitic diode, because the discharge current flows through the parasitic diode in the charging control FET. If this VM pin voltage is higher than or equal to V_{DIOV}, the S-8252 Series releases the overcharge status when the battery voltage is lower than or equal to V_{CU}.

Caution 1. If the battery is charged to a voltage higher than V_{CU} and the battery voltage does not fall below V_{CU} even when a heavy load is connected, discharge overcurrent detection and load short-circuiting detection do not function until the battery voltage falls below V_{CU}. Since an actual battery has an internal impedance of tens of mΩ, the battery voltage drops immediately after a heavy load that causes overcurrent is connected, and discharge overcurrent detection and load short-circuiting detection function.
2. If a charger is connected after the overcharge detection, the overcharge status is not released even when the battery voltage falls below V_{CL}. The S-8252 Series releases the overcharge status when the VM pin voltage returns to V_{CIOV} (or V_{CHA} when without charge overcurrent detection function) or higher by removing the charger.

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3. Overdischarge status

When the battery voltage falls below overdischarge detection voltage (V_{DL}) during discharging in the normal status and the condition continues for the overdischarge detection delay time (t_{DL}) or longer, the S-8252 Series turns the discharging control FET off to stop discharging. This condition is called the overdischarge status.
Under the overdischarge status, the VM pin and VDD pin are shorted by R_{VMD} in the S-8252 Series. The VM pin is pulled up by R_{VMD}.
R_{VMS} is not connected in the overdischarge status.

3. 1 With power-down function

Under the overdischarge status, when voltage difference between the VM pin and VDD pin is 0.8 V typ. or lower, the power-down function works and the current consumption is reduced to the current consumption during power-down (I_{PDN}). By connecting a battery charger, the power-down function is released when the VM pin voltage is 0.7 V typ. or lower.

- When a battery is not connected to a charger and the VM pin voltage ≥ 0.7 V typ., the S-8252 Series maintains the overdischarge status even when the battery voltage reaches V_{DU} or higher.
- When a battery is connected to a charger and 0.7 V typ. > the VM pin voltage > –0.7 V typ., the battery voltage reaches V_{DU} or higher and the S-8252 Series releases the overdischarge status.
- When a battery is connected to a charger and –0.7 V typ. ≥ the VM pin voltage, the battery voltage reaches V_{DL} or higher and the S-8252 Series releases the overdischarge status.

3. 2 Without power-down function

The power-down function does not work even when voltage difference between the VM pin and VDD pin is 0.8 V typ. or lower.

- When a battery is not connected to a charger and the VM pin voltage ≥ 0.7 V typ., the battery voltage reaches V_{DU} or higher and the S-8252 Series releases the overdischarge status.
- When a battery is connected to a charger and 0.7 V typ. > the VM pin voltage > –0.7 V typ., the battery voltage reaches V_{DU} or higher and the S-8252 Series releases the overdischarge status.
- When a battery is connected to a charger and –0.7 V typ. ≥ the VM pin voltage, the battery voltage reaches V_{DL} or higher and the S-8252 Series releases the overdischarge status.

4. Discharge overcurrent status (Discharge overcurrent, load short-circuiting)

When a battery in the normal status is in the status where the voltage of the VM pin is equal to or higher than V_{DIOV} because the discharge current is equal to or higher than the specified value and the status lasts for the discharge overcurrent detection delay time (t_{DIOV}) or longer, the discharge control FET is turned off and discharging is stopped. This status is called the discharge overcurrent status.
In the discharge overcurrent status, the VM pin and VSS pin are shorted by the R_{VMS} in the S-8252 Series. However, the voltage of the VM pin is at the V_{DD} potential due to the load as long as the load is connected. When the load is disconnected, the VM pin returns to the V_{SS} potential.
If the voltage at the VM pin returns to V_{DIOV} or lower, the S-8252 Series releases the discharge overcurrent status.
R_{VMD} is not connected in the discharge overcurrent detection status.

5. Charge overcurrent status (with charge overcurrent detection function)

When a battery in the normal status is in the status where the voltage of the VM pin is equal to or lower than V_{CIOV} because the charge current is equal to or higher than the specified value and the status lasts for the charge overcurrent detection delay time (t_{CIOV}) or longer, the charge control FET is turned off and charging is stopped. This status is called the charge overcurrent status.
The S-8252 Series releases the charge overcurrent status when the voltage at the VM pin returns to V_{CIOV} or higher by removing the charger.
The charge overcurrent detection function does not work in the overdischarge status.
R_{VMD} and R_{VMS} are not connected in the charge overcurrent detection status.

6. Abnormal charge current status (without charge overcurrent detection function)

If the VM pin voltage falls below the charger detection voltage (V_{CHA}) during charging under normal status and it continues for the overcharge detection delay time (t_{CU}) or longer, the charging control FET turns off and charging stops. This action is called the abnormal charge current status.
Abnormal charge current status is released when the voltage difference between VM pin and VSS pin becomes less than charger detection voltage (V_{CHA}).

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7. 0 V battery charge enabled

This function is used to recharge a connected battery whose voltage is 0 V due to self-discharge. When the 0 V battery charge starting charger voltage (V_{0CHA}) or a higher voltage is applied between the EB+ and EB− pins by connecting a charger, the charging control FET gate is fixed to the V_{DD} potential.
When the voltage between the gate and source of the charging control FET becomes equal to or higher than the threshold voltage due to the charger voltage, the charging control FET is turned on to start charging. At this time, the discharging control FET is off and the charging current flows through the internal parasitic diode in the discharging control FET. When the battery voltage becomes equal to or higher than V_{DU}, the S-8252 Series returns to the normal status.

Caution
1. **Some battery providers do not recommend recharging for a completely self-discharged battery. Please ask the battery provider to determine whether to enable or inhibit the 0 V battery charge.**
2. **The 0 V battery charge has higher priority than the charge overcurrent detection function. Consequently, a product in which use of the 0 V battery charge is enabled charges a battery forcibly and the charge overcurrent cannot be detected when the battery voltage is lower than V_{DL}.**

8. 0 V battery charge inhibited

This function inhibits charging when a battery that is internally short-circuited (0 V battery) is connected. When the battery voltage is the 0 V battery charge inhibition battery voltage (V_{0INH}) or lower, the charging control FET gate is fixed to the EB− pin voltage to inhibit charging. When the battery voltage is V_{0INH} or higher, charging can be performed.

Caution **Some battery providers do not recommend recharging for a completely self-discharged battery. Please ask the battery provider to determine whether to enable or inhibit the 0 V battery charge.**

9. Delay circuit

The detection delay times are determined by dividing a clock of approximately 4 kHz by the counter.

Remark t_{DIOV} and t_{SHORT} start when V_{DIOV} is detected. When V_{SHORT} is detected over t_{SHORT} after V_{DIOV}, the S-8252 Series turns the discharging control FET off within t_{SHORT} from the time of detecting V_{SHORT}.

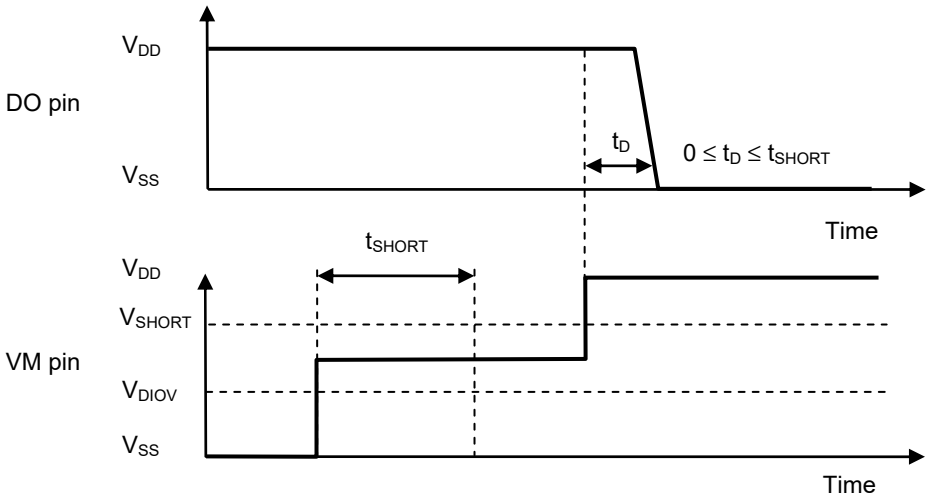
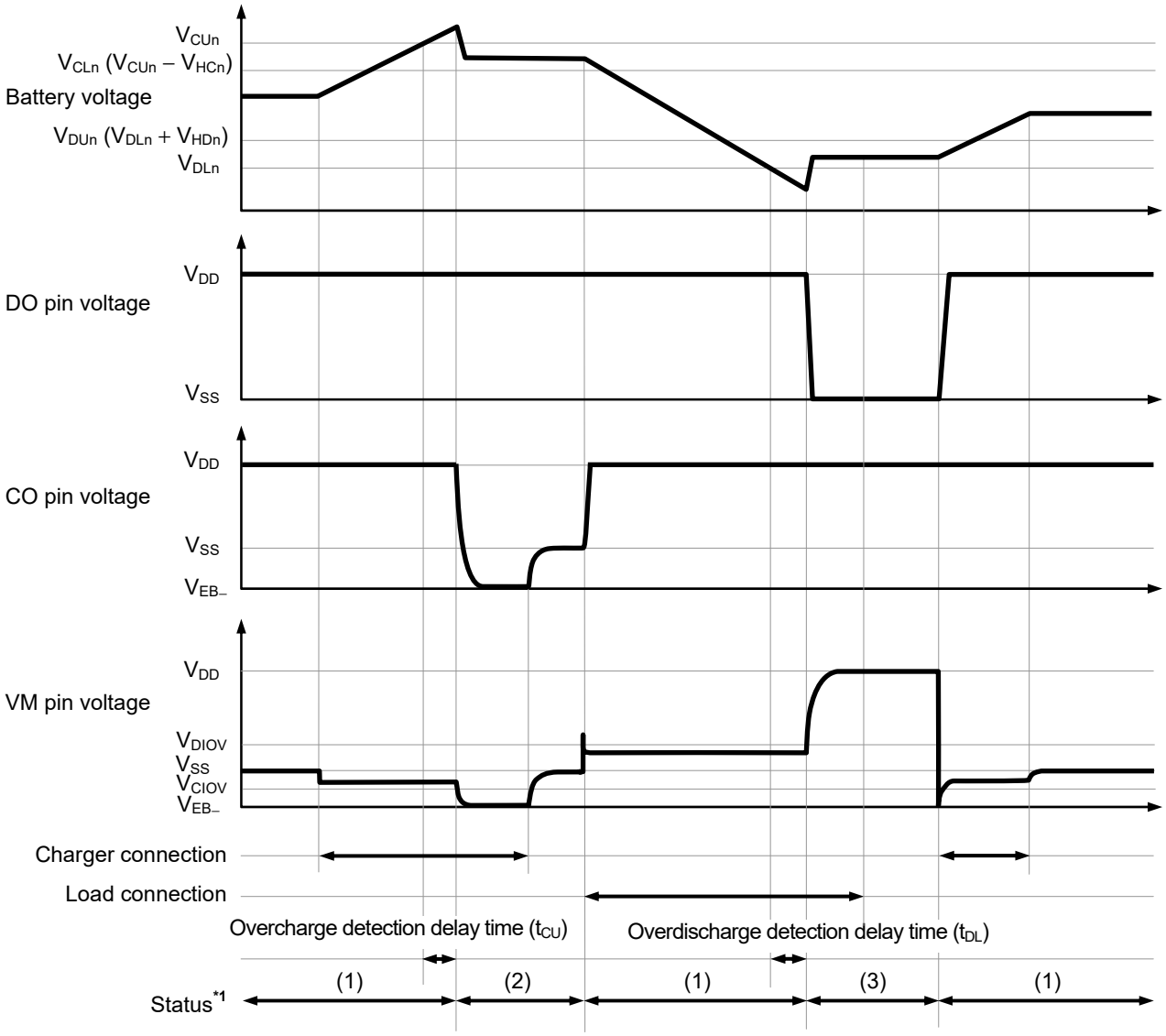


Figure 10

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■ Timing Chart

1. Overcharge detection, overdischarge detection



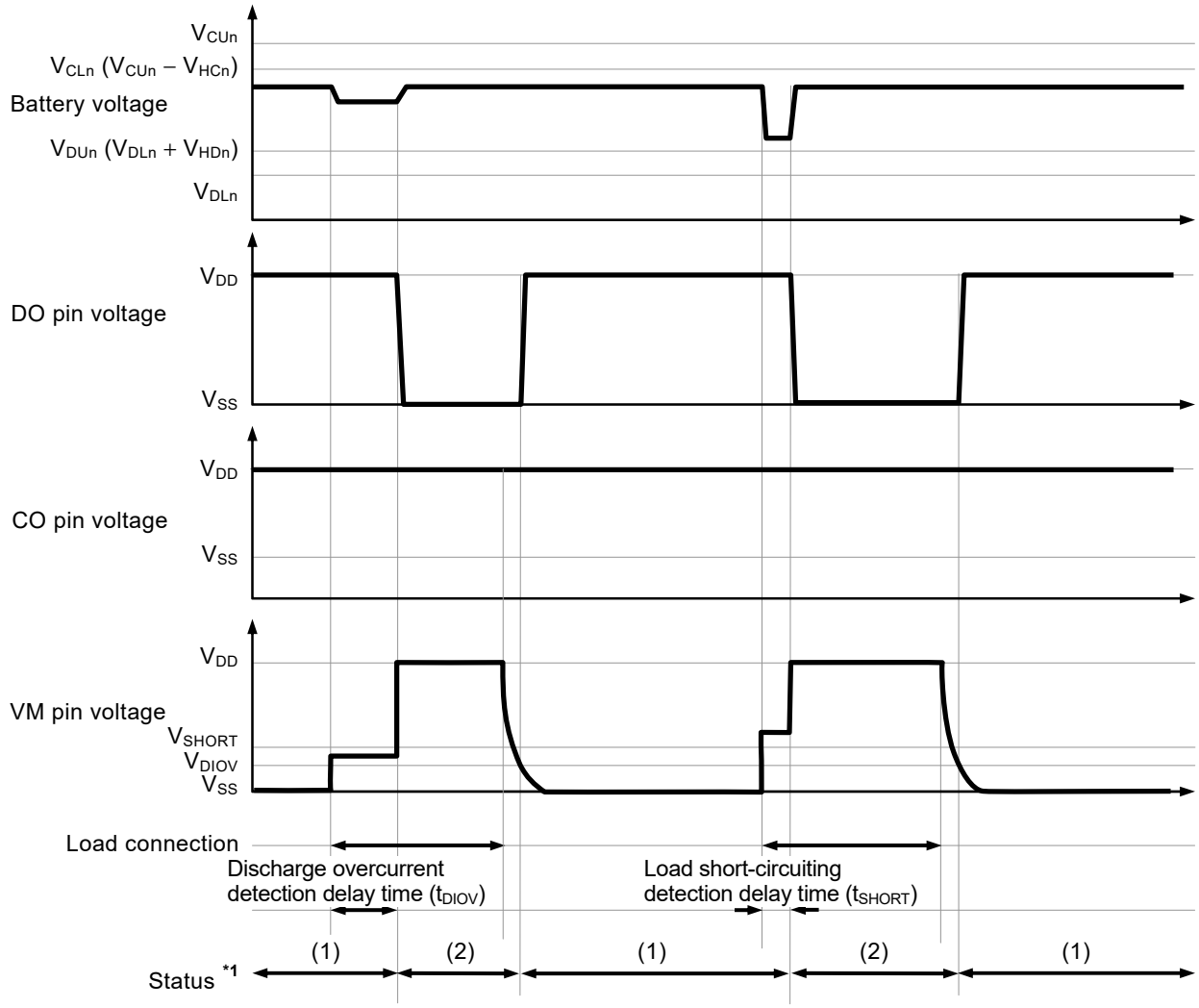
***1.** (1): Normal status
(2): Overcharge status
(3): Overdischarge status

Remark The charger is assumed to charge with a constant current.

Figure 11

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2. Discharge overcurrent detection



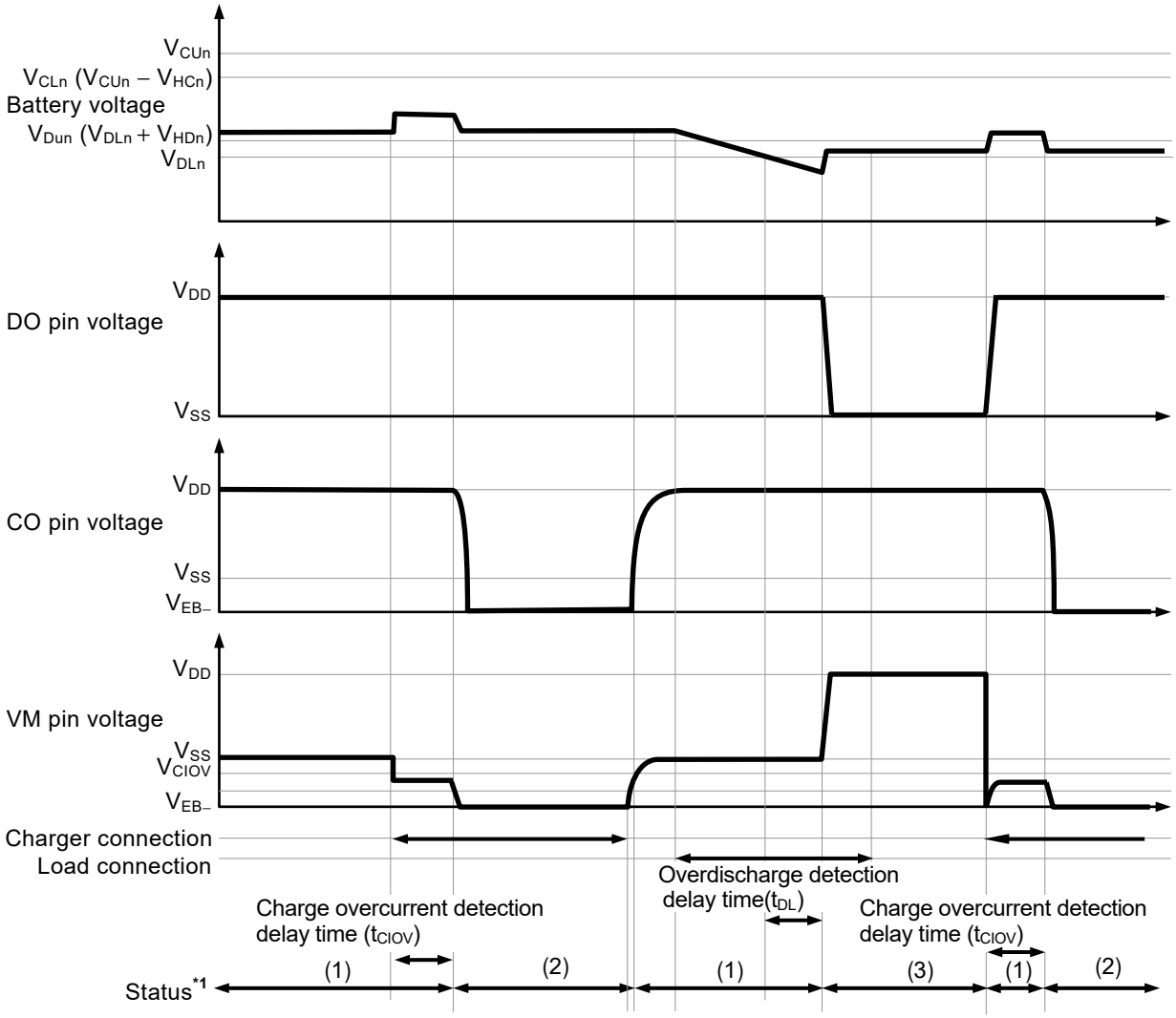
***1**. (1): Normal status
(2): Discharge overcurrent status

Remark The charger is assumed to charge with a constant current.

Figure 12

Downloaded from Arrow.com.

3. Charge overcurrent detection



***1.** (1): Normal status
(2): Charge overcurrent status
(3): Overdischarge status

Remark The charger is assumed to charge with a constant current.

Figure 13

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■ Battery Protection IC Connection Example

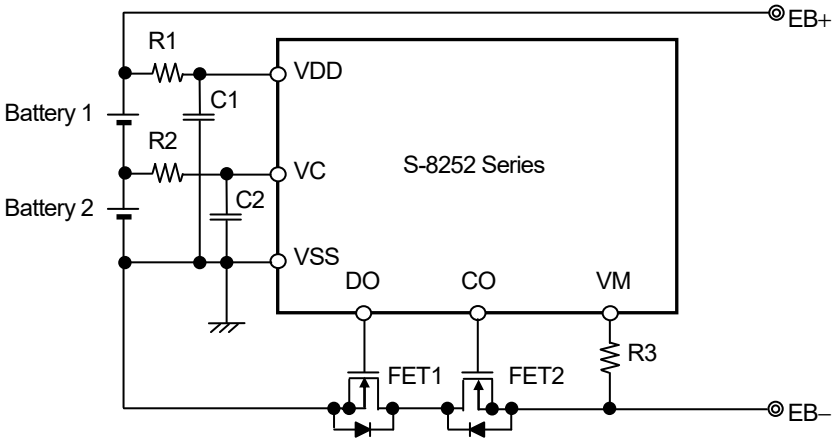


Figure 14

Table 11 Constants for External Components

Symbol	Part	Purpose	Typ.	Min.	Max.	Remark
FET1	N-channel MOS FET	Discharge control	–	–	–	Threshold voltage ≤ Overdischarge detection voltage*2 Gate to source withstand voltage ≥ Charger voltage*3
FET2	N-channel MOS FET	Charge control	–	–	–	Threshold voltage ≤ Overdischarge detection voltage*2 Gate to source withstand voltage ≥ Charger voltage*3
R1, R2	Resistor	ESD protection, For power fluctuation	470 Ω	150 Ω*1	1 kΩ*1	Resistance should be as small as possible to avoid lowering the overcharge detection accuracy due to current consumption.*4
C1, C2	Capacitor	For power fluctuation	0.1 μF	0.068 μF*1	1.0 μF*1	Connect a capacitor of 0.068 μF or higher between VDD pin and VSS pin.*5
R3	Resistor	Protection for reverse connection of a charger	2 kΩ	300 Ω*1	4 kΩ*1	Select as large a resistance as possible to prevent current when a charger is connected in reverse.*6

***1.** Please set up a filter constant to be R1 × C1 = R2 × C2.

***2.** If the threshold voltage of an FET is low, the FET may not cut the charge current. If an FET with a threshold voltage equal to or higher than the overdischarge detection voltage is used, discharging may be stopped before overdischarge is detected.

***3.** If the withstand voltage between the gate and source is equal to or lower than the charger voltage, the FET may be destroyed.

***4.** An accuracy of overcharge detection voltage is guaranteed by R1 = 470 Ω. Connecting resistors with other values worsen the accuracy. In case of connecting larger resistor to R1, the voltage between the VDD pin and VSS pin may exceed the absolute maximum rating because the current flows to the S-8252 Series from the charger due to reverse connection of charger. Connect a resistor of 150 Ω or more to R1 for ESD protection.

***5.** When connecting a resistor of 150 Ω or less to R1 or R2 or a capacitor of 0.068 μF or less to C1 or C2, the S-8252 Series may malfunction when power dissipation is largely fluctuated.

***6.** When a resistor of 4 kΩ or more is connected to R3, the charge current may not be cut.

Caution 1. The constants may be changed without notice.

2. It has not been confirmed whether the operation is normal or not in circuits other than the connection example. In addition, the connection example and the constants do not guarantee proper operation. Perform thorough evaluation using the actual application to set the constants.

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■ Precautions

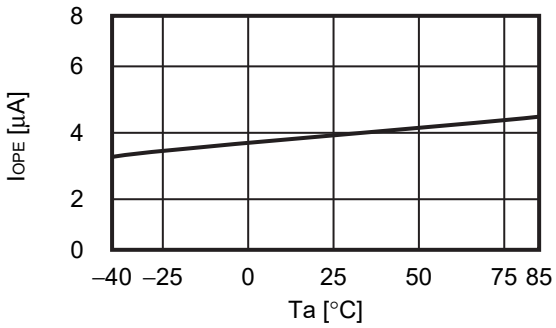
- The application conditions for the input voltage, output voltage, and load current should not exceed the package power dissipation.
- Do not apply an electrostatic discharge to this IC that exceeds the performance ratings of the built-in electrostatic protection circuit.
- ABLIC Inc. claims no responsibility for any and all disputes arising out of or in connection with any infringement by products including this IC of patents owned by a third party.

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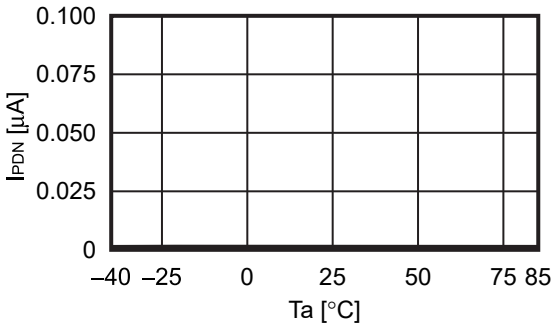
■ Characteristics (Typical Data)

1. Current consumption

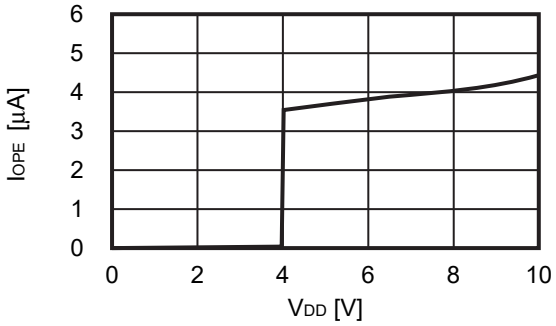
1. 1 I_{OPE} vs. Ta



1. 2 I_{PDN} vs. Ta



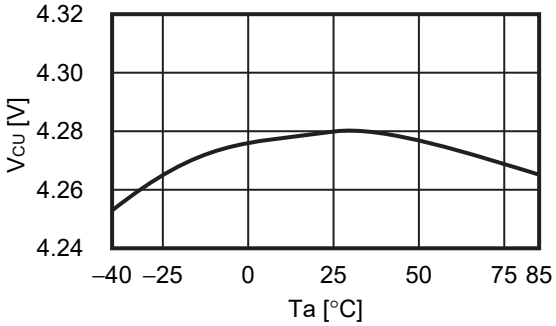
1. 3 I_{OPE} vs. V_{DD}



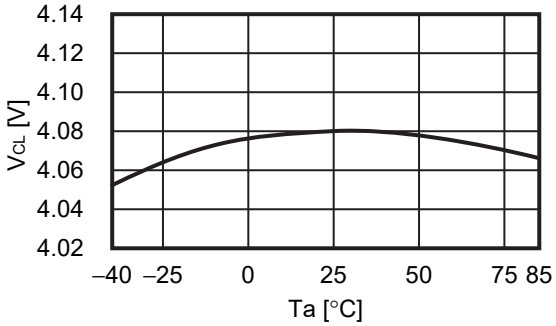
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2. Overcharge detection / release voltage, overdischarge detection / release voltage, overcurrent detection voltage, charge overcurrent detection voltage, and delay time

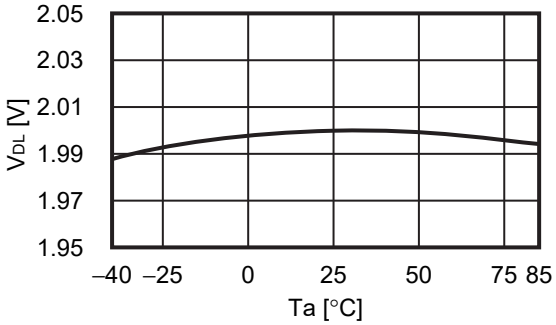
2. 1 V_{CU} vs. Ta



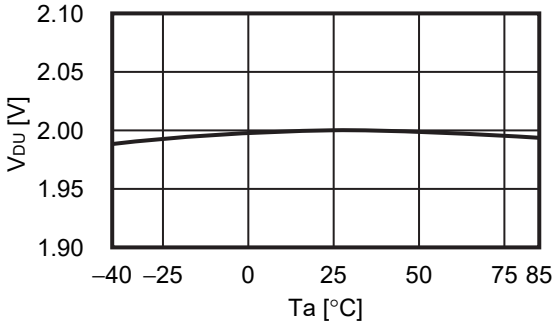
2. 2 V_{CL} vs. Ta



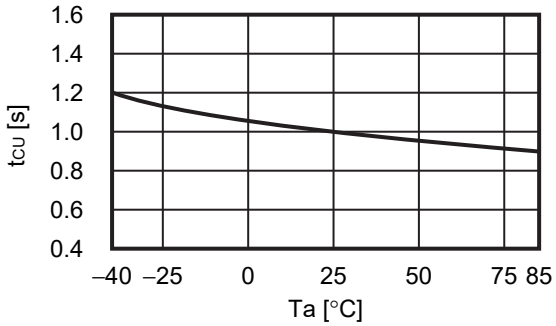
2. 3 V_{DL} vs. Ta



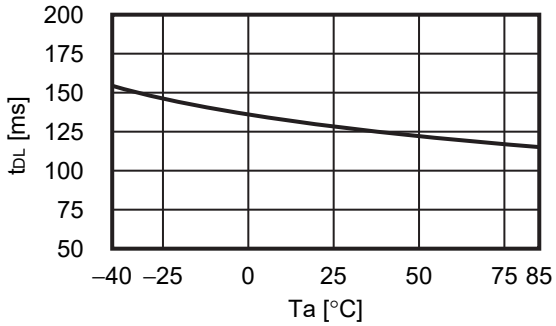
2. 4 V_{DU} vs. Ta



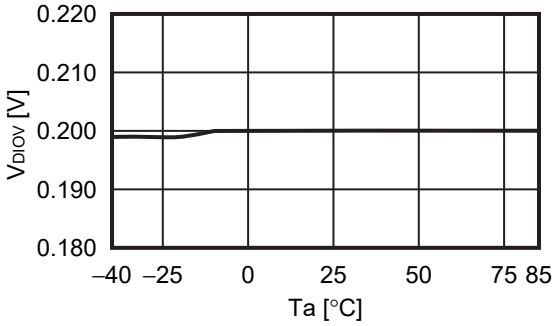
2. 5 t_{CU} vs. Ta



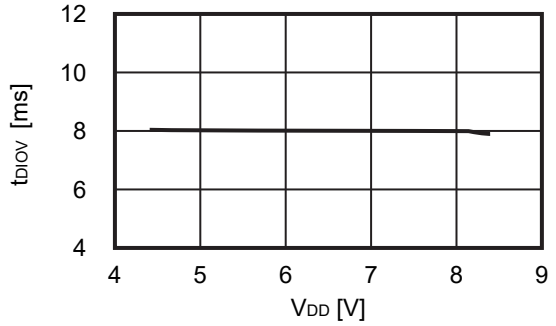
2. 6 t_{DL} vs. Ta



2. 7 V_{DIOV} vs. Ta

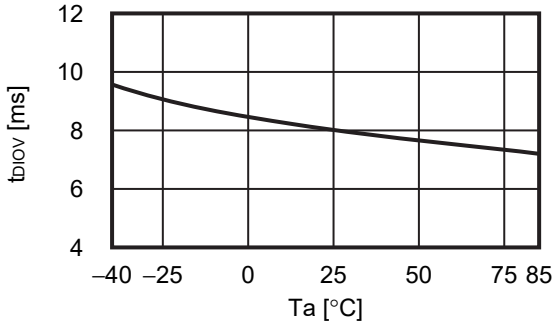


2. 8 t_{DIOV} vs. V_{DD}

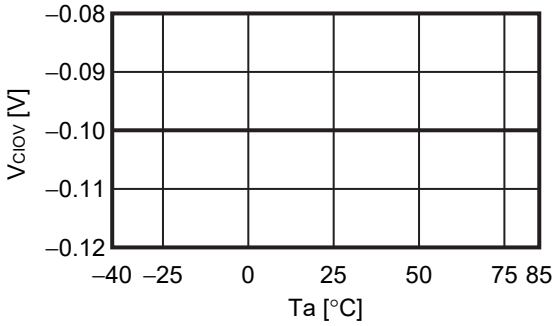


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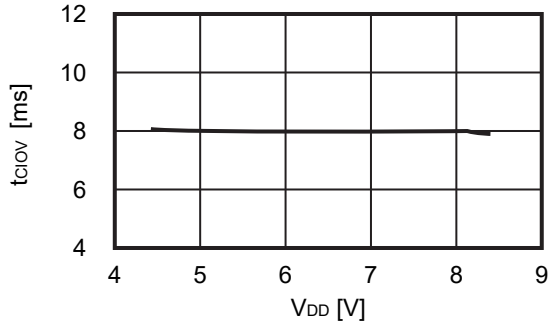
2. 9 t_{DIOV} vs. Ta



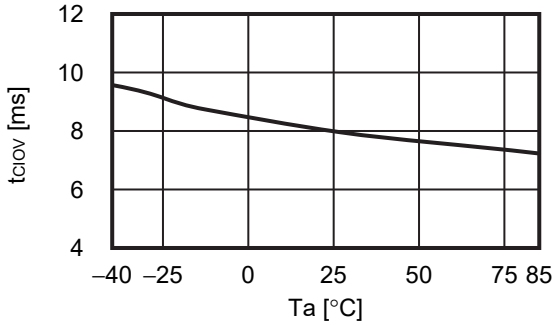
2. 10 V_{CIOV} vs. Ta



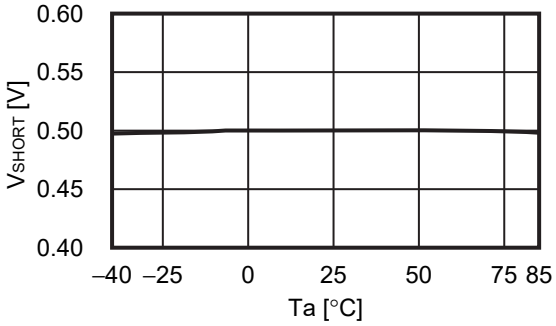
2. 11 t_{CIOV} vs. V_{DD}



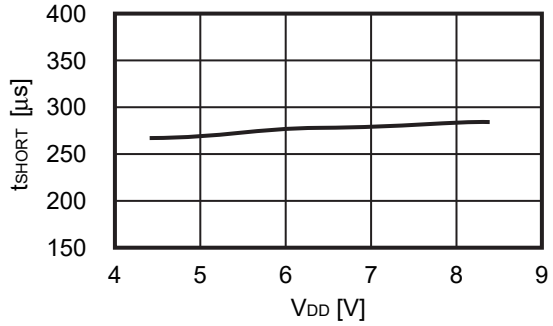
2. 12 t_{CIOV} vs. Ta



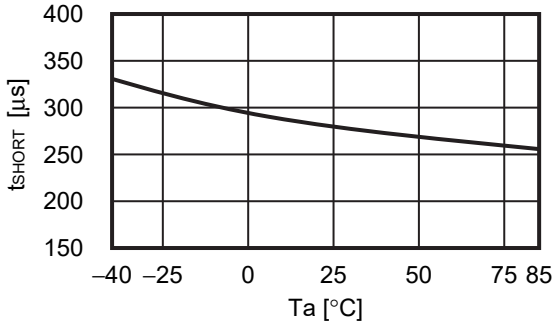
2. 13 V_{SHORT} vs. Ta



2. 14 t_{SHORT} vs. V_{DD}



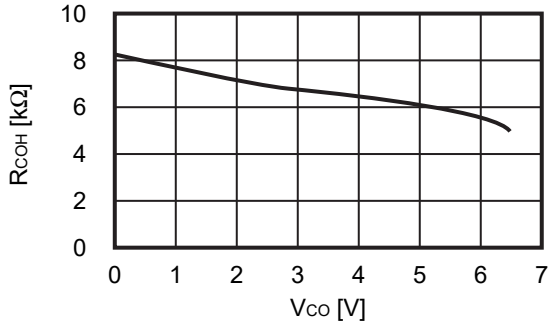
2. 15 t_{SHORT} vs. Ta



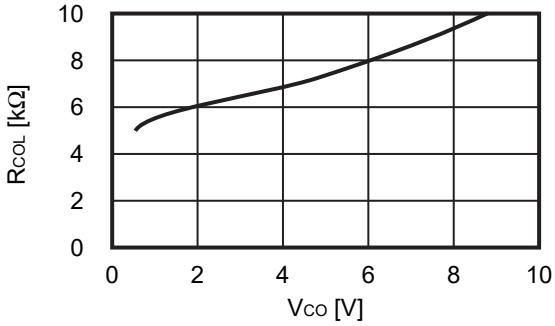
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3. CO pin / DO pin

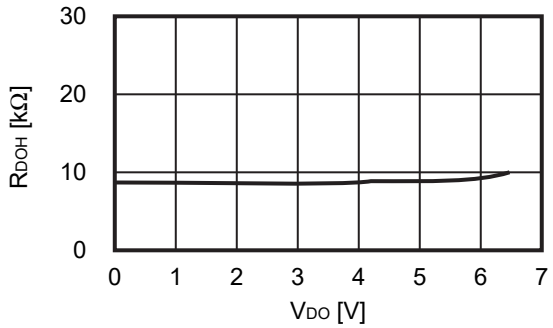
3. 1 R_{COH} vs. V_{CO}



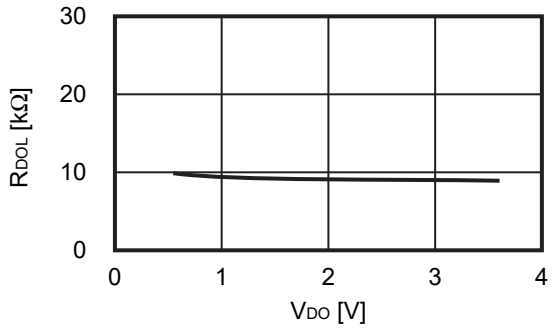
3. 2 R_{COL} vs. V_{CO}



3. 3 R_{DOH} vs. V_{DO}



3. 4 R_{DOL} vs. V_{DO}

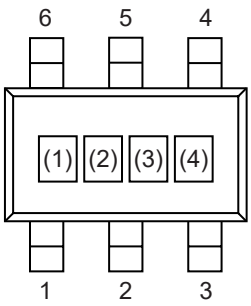


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■ Marking Specifications

1. SOT-23-6

Top view



(1) to (3): Product code (Refer to **Product name vs. Product code**)
(4): Lot number

Product name vs. Product code

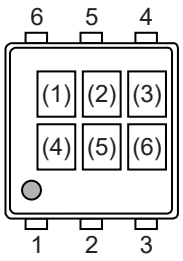
Product Name	Product Code		
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S-8252AAB-M6T1U	C	G	B
S-8252AAC-M6T1U	C	G	C
S-8252AAD-M6T1U	C	G	D
S-8252AAE-M6T1U	C	G	E
S-8252AAF-M6T1U	C	G	F
S-8252AAG-M6T1U	C	G	G
S-8252AAH-M6T1U	C	G	H
S-8252AAI-M6T1U	C	G	I
S-8252AAJ-M6T1U	C	G	J
S-8252AAK-M6T1U	C	G	K
S-8252AAL-M6T1U	C	G	L
S-8252AAO-M6T1U	C	G	O
S-8252AAP-M6T1U	C	G	P
S-8252AAQ-M6T1U	C	G	Q
S-8252AAR-M6T1U	C	G	R
S-8252AAS-M6T1U	C	G	S
S-8252AAT-M6T1U	C	G	T
S-8252AAU-M6T1U	C	G	U
S-8252AAV-M6T1U	C	G	V
S-8252AAW-M6T1U	C	G	W
S-8252AAX-M6T1U	C	G	X
S-8252AAY-M6T1U	C	G	Y
S-8252AAZ-M6T1U	C	G	Z
S-8252ABA-M6T1U	C	H	A
S-8252ABB-M6T1U	C	H	B
S-8252ABC-M6T1U	C	H	C
S-8252ABD-M6T1U	C	H	D
S-8252ABE-M6T1U	C	H	E
S-8252ABF-M6T1U	C	H	F
S-8252ABG-M6T1U	C	H	G
S-8252ABH-M6T1U	C	H	H

Product Name	Product Code		
	(1)	(2)	(3)
S-8252ABI-M6T1U	C	H	I
S-8252ABQ-M6T1U	C	H	Q
S-8252ABR-M6T1U	C	H	R
S-8252ABS-M6T1U	C	H	S
S-8252ABT-M6T1U	C	H	T
S-8252ABU-M6T1U	C	H	U
S-8252ABV-M6T1U	C	H	V
S-8252ABW-M6T1U	C	H	W
S-8252ABX-M6T1U	C	H	X
S-8252ABY-M6T1U	C	H	Y
S-8252ABZ-M6T1U	C	H	Z
S-8252ACA-M6T1U	C	B	A
S-8252ACB-M6T1U	C	B	B
S-8252ACC-M6T1U	C	B	C
S-8252ACE-M6T1U	C	B	E
S-8252ACF-M6T1U	C	B	F
S-8252ACI-M6T1U	C	B	I
S-8252ACM-M6T1U	C	B	M
S-8252ACN-M6T1U	C	B	N
S-8252ACO-M6T1U	C	B	O
S-8252ACP-M6T1U	C	B	P
S-8252ACQ-M6T1U	C	B	Q
S-8252ACR-M6T1U	C	B	R
S-8252ACS-M6T1U	C	B	S
S-8252ACT-M6T1U	C	B	T
S-8252ACU-M6T1U	C	B	U
S-8252ACV-M6T1U	C	B	V
S-8252ACW-M6T1U	C	B	W
S-8252ACX-M6T1U	C	B	X
S-8252ACY-M6T1U	C	B	Y
S-8252ADC-M6T1U	C	1	C

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2. SNT-6A

Top view

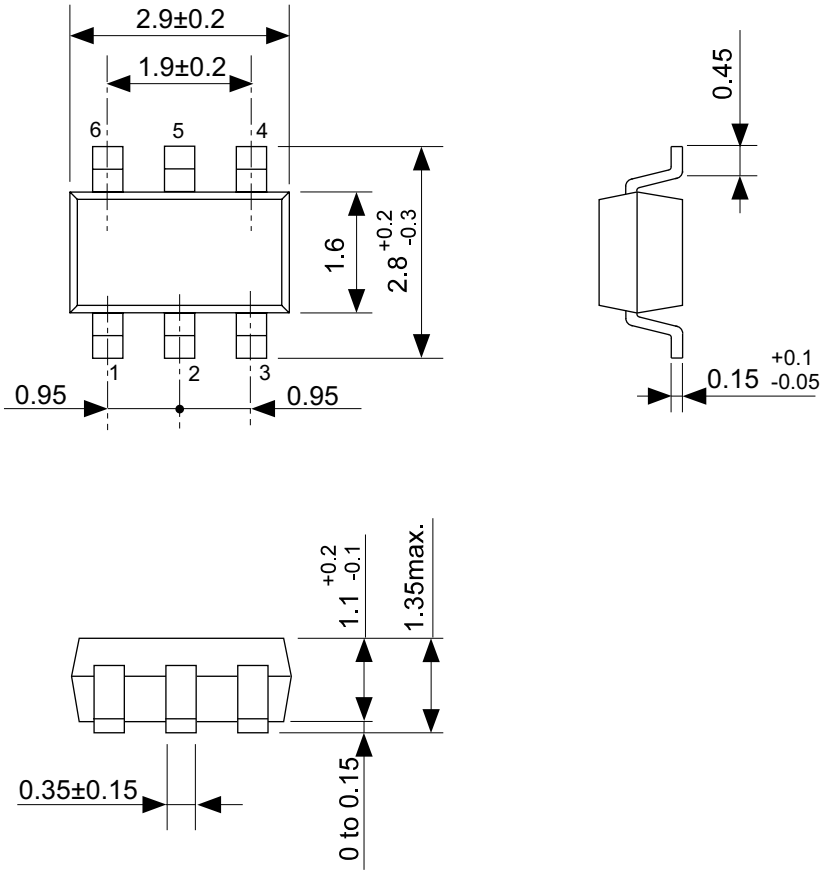


(1) to (3): Product code (Refer to **Product name vs. Product code**)
(4) to (6): Lot number

Product name vs. Product code

Product Name	Product Code		
	(1)	(2)	(3)
S-8252AAA-I6T1U	C	G	A
S-8252AAH-I6T1U	C	G	H
S-8252AAM-I6T1U	C	G	M
S-8252AAN-I6T1U	C	G	N
S-8252AAY-I6T1U	C	G	Y
S-8252ABJ-I6T1U	C	H	J
S-8252ABK-I6T1U	C	H	K
S-8252ABL-I6T1U	C	H	L
S-8252ABM-I6T1U	C	H	M
S-8252ABO-I6T1U	C	H	O
S-8252ABP-I6T1U	C	H	P
S-8252ACD-I6T1U	C	B	D
S-8252ACG-I6T1U	C	B	G
S-8252ACH-I6T1U	C	B	H
S-8252ACJ-I6T1U	C	B	J
S-8252ACK-I6T1U	C	B	K
S-8252ACL-I6T1U	C	B	L
S-8252ACZ-I6T1U	C	B	Z
S-8252ADA-I6T1U	C	1	A
S-8252ADB-I6T1U	C	1	B
S-8252ADD-I6T1U	C	1	D
S-8252ADE-I6T1U	C	1	E
S-8252ADF-I6T1U	C	1	F
S-8252ADH-I6T1U	C	1	H
S-8252ADI-I6T1U	C	1	I
S-8252ADJ-I6T1U	C	1	J
S-8252ADK-I6T1U	C	1	K
S-8252ADL-I6T1U	C	1	L
S-8252ADM-I6T1U	C	1	M

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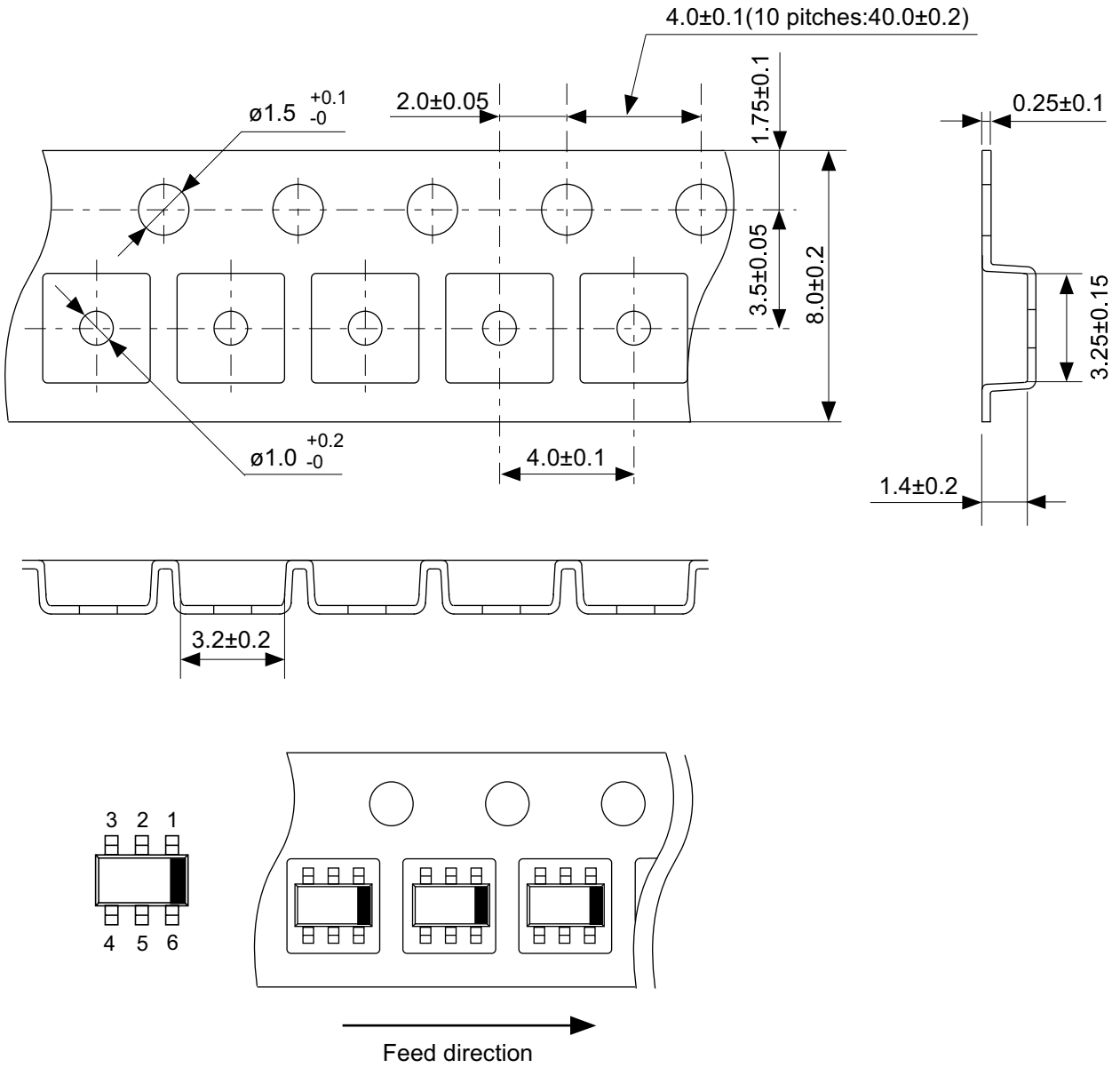


No. MP006-A-P-SD-2.1

TITLE	SOT236-A-PKG Dimensions
No.	MP006-A-P-SD-2.1
ANGLE	
UNIT	mm

ABLIC Inc.

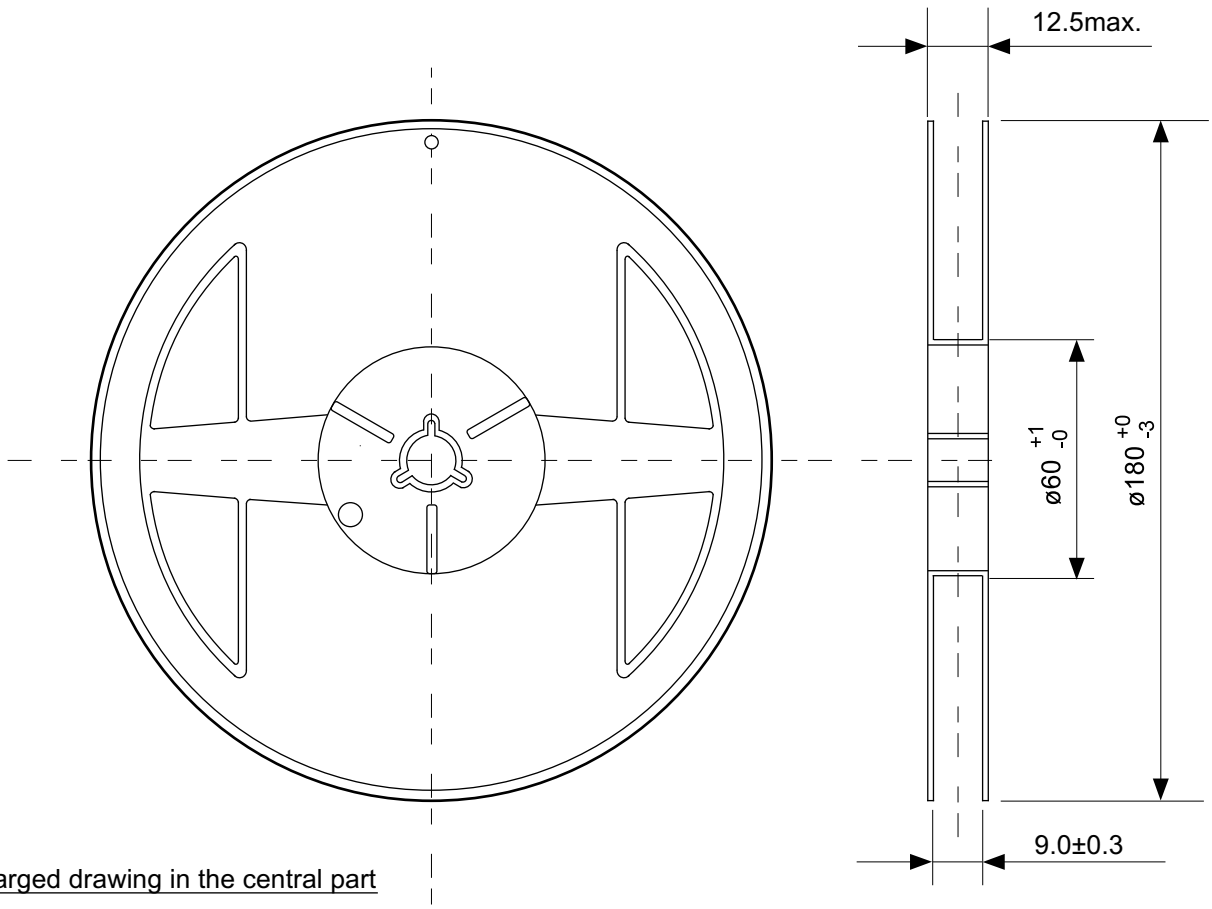
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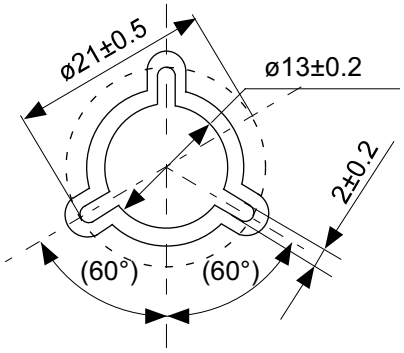
No. MP006-A-C-SD-3.1

TITLE	SOT236-A-Carrier Tape
No.	MP006-A-C-SD-3.1
ANGLE	
UNIT	mm
ABLIC Inc.	

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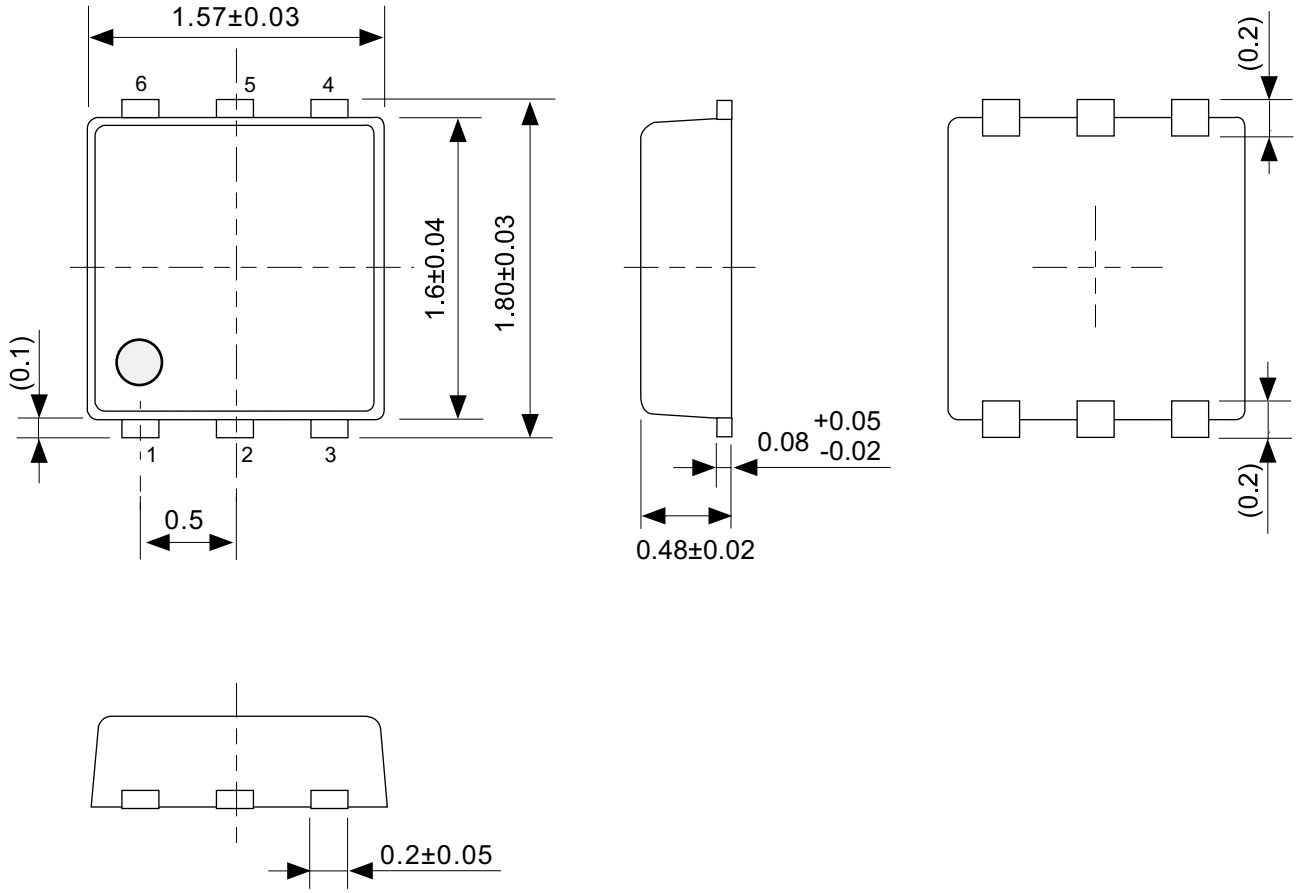
Enlarged drawing in the central part



No. MP006-A-R-SD-2.1

TITLE	SOT236-A-Reel		
No.	MP006-A-R-SD-2.1		
ANGLE		QTY	3,000
UNIT	mm		
ABLIC Inc.			

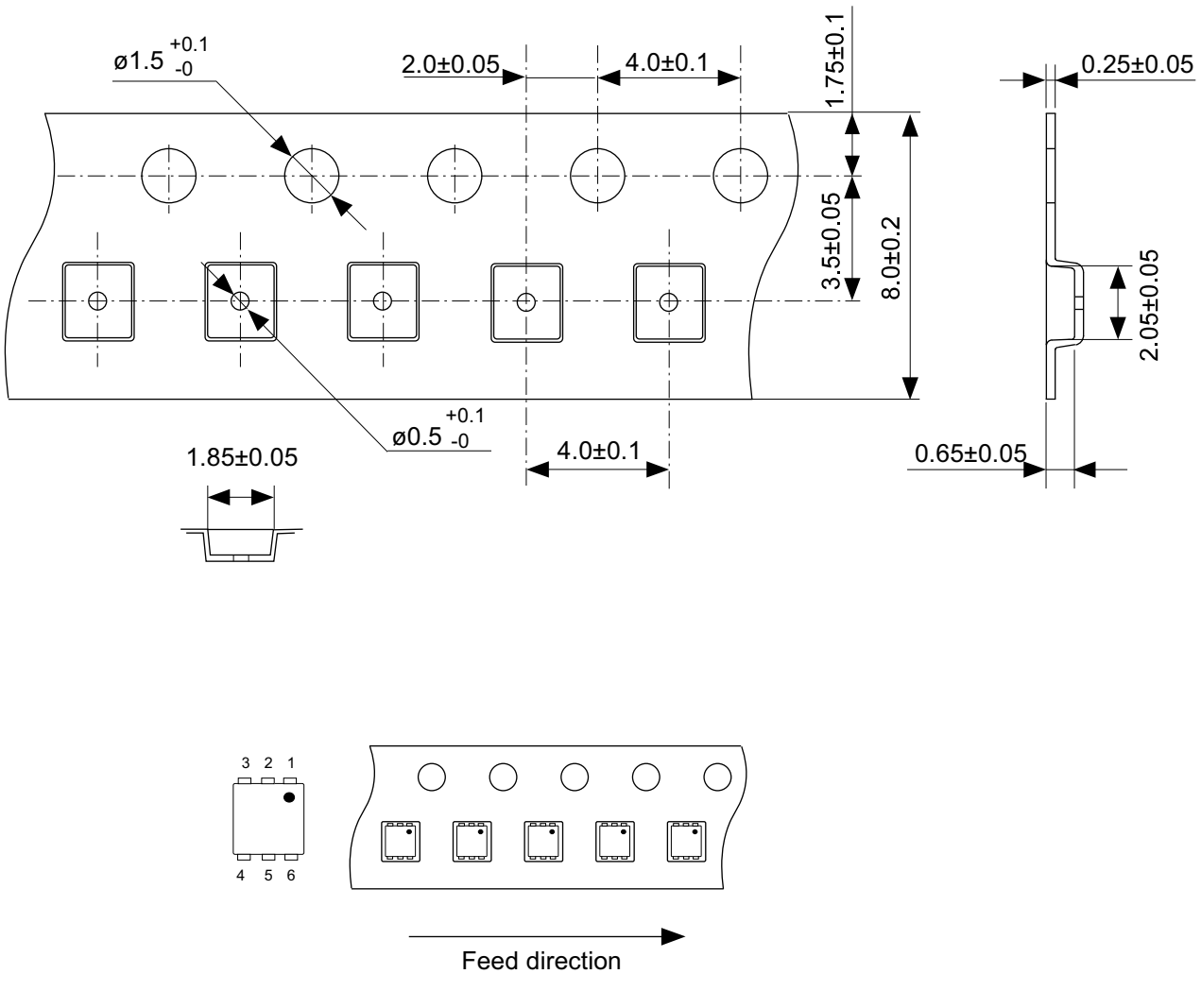
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No. PG006-A-P-SD-2.1

TITLE	SNT-6A-A-PKG Dimensions
No.	PG006-A-P-SD-2.1
ANGLE	
UNIT	mm
ABLIC Inc.	

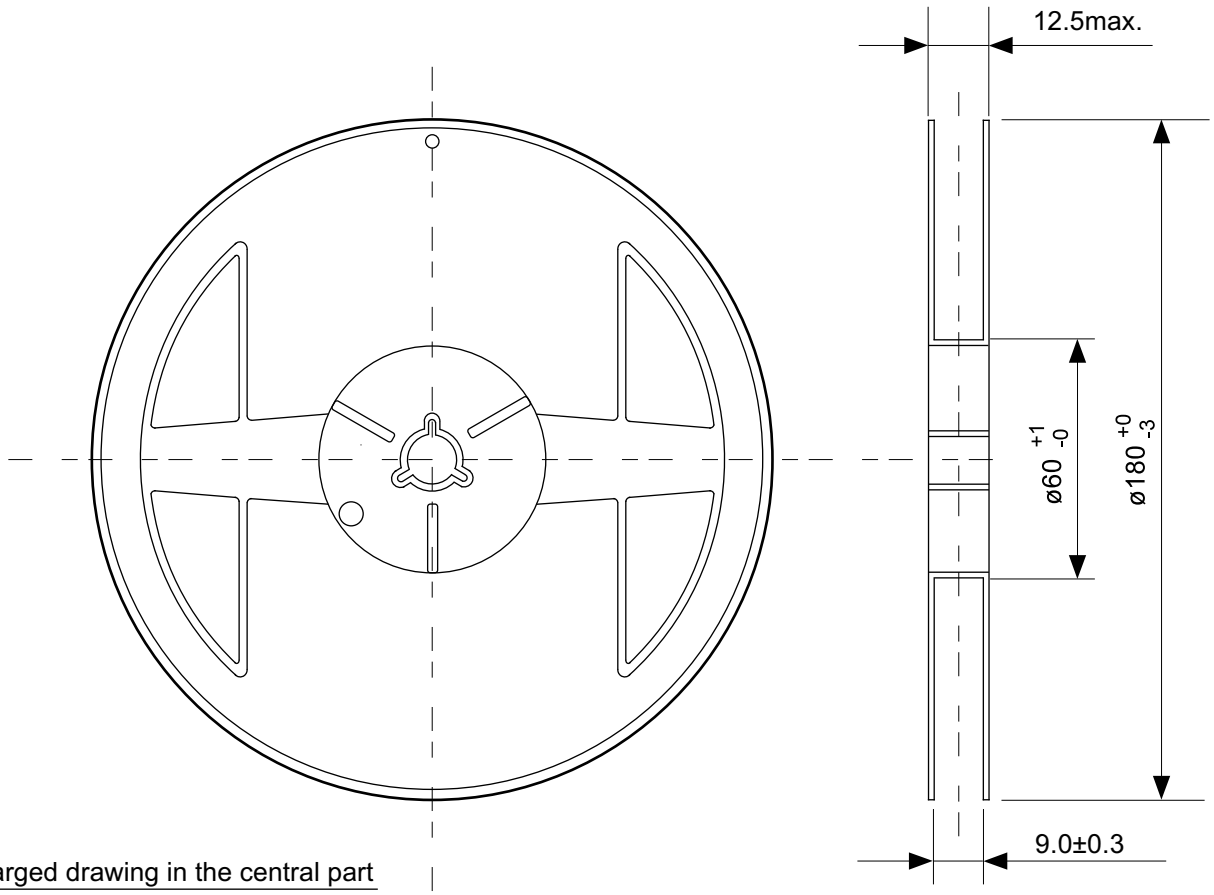
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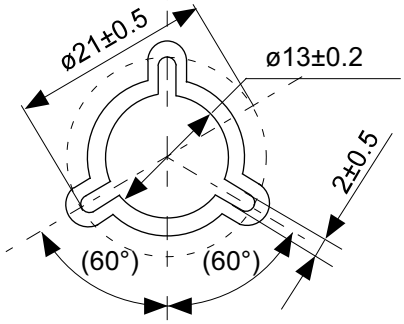
No. PG006-A-C-SD-2.0

TITLE	SNT-6A-A-Carrier Tape
No.	PG006-A-C-SD-2.0
ANGLE	
UNIT	mm
ABLIC Inc.	

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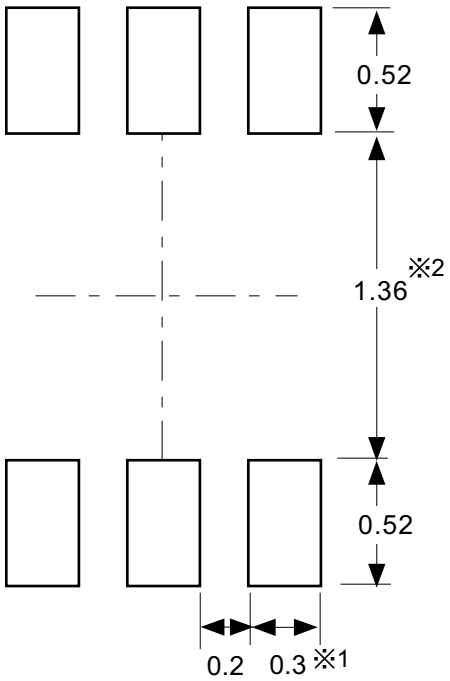
Enlarged drawing in the central part



No. PG006-A-R-SD-1.0

TITLE	SNT-6A-A-Reel		
No.	PG006-A-R-SD-1.0		
ANGLE		QTY.	5,000
UNIT	mm		
ABLIC Inc.			

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※1. ランドパターンの幅に注意してください (0.25 mm min. / 0.30 mm typ.)。
※2. パッケージ中央にランドパターンを広げないでください (1.30 mm ~ 1.40 mm)。

注意 1. パッケージのモールド樹脂下にシルク印刷やハンダ印刷などしないでください。
2. パッケージ下の配線上のソルダーレジストなどの厚みをランドパターン表面から**0.03 mm** 以下にしてください。
3. マスク開口サイズと開口位置はランドパターンと合わせてください。
4. 詳細は〝**SNT**パッケージ活用の手引き〟を参照してください。

※1. Pay attention to the land pattern width (0.25 mm min. / 0.30 mm typ.).
※2. Do not widen the land pattern to the center of the package (1.30 mm ~ 1.40 mm).

Caution 1. Do not do silkscreen printing and solder printing under the mold resin of the package.
2. The thickness of the solder resist on the wire pattern under the package should be 0.03 mm or less from the land pattern surface.
3. Match the mask aperture size and aperture position with the land pattern.
4. Refer to "SNT Package User's Guide" for details.

※1. 请注意焊盘模式的宽度 (0.25 mm min. / 0.30 mm typ.)。
※2. 请勿向封装中间扩展焊盘模式 (1.30 mm ~ 1.40 mm)。

注意 1. 请勿在树脂型封装的下面印刷丝网、焊锡。
2. 在封装下、布线上的阻焊膜厚度 (从焊盘模式表面起) 请控制在 0.03 mm 以下。
3. 钢网的开口尺寸和开口位置请与焊盘模式对齐。
4. 详细内容请参阅 "SNT 封装的应用指南"。

No. PG006-A-L-SD-4.1

TITLE	SNT-6A-A -Land Recommendation
No.	PG006-A-L-SD-4.1
ANGLE	
UNIT	mm
ABLIC Inc.	

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